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# **Polymer-Assisted Deposition (PAD) and Its Applications**

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Los Alamos, NM 87545

**LA-UR-14-22920**

# DOE National Laboratories



U.S. DEPARTMENT OF  
**ENERGY**

# BES Nanoscale Science Research Centers (NSRCs)



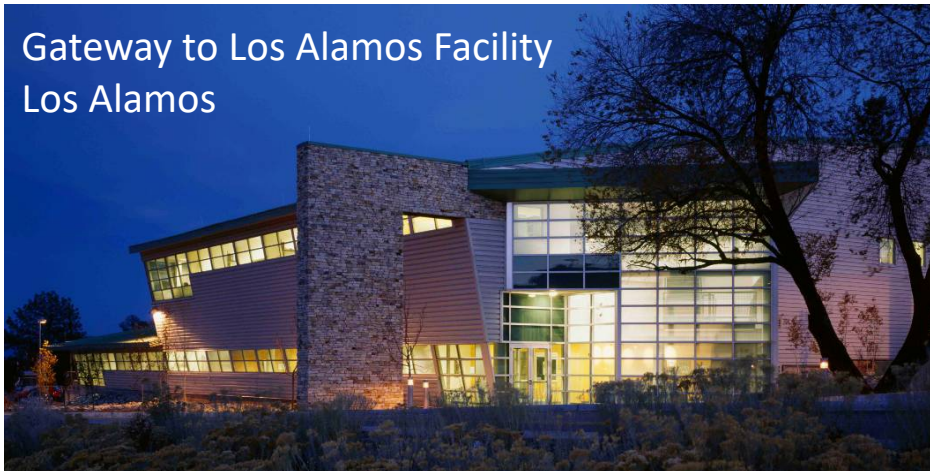




# Center for Integrated Nanotechnologies

**CINT: A DOE User Facility for nanoscience research at**  
*Los Alamos and Sandia National Laboratories*

Gateway to Los Alamos Facility  
Los Alamos



- New Science
- New Tools
- Innovative approaches to nanoscale integration

Core Facility, Sandia National Laboratories Albuquerque

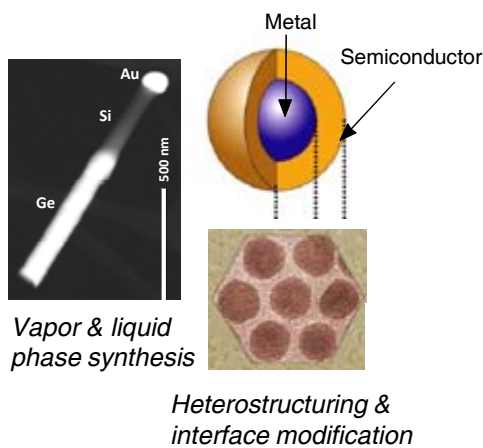




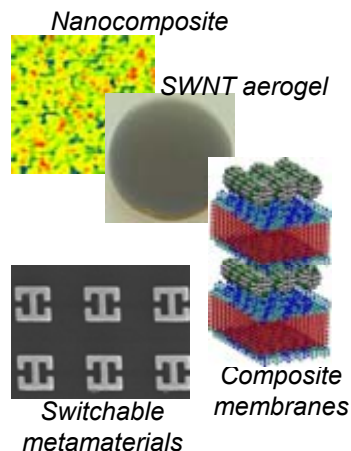
# The CINT Vision & Mission

*One scientific community focused on nanoscience integration*

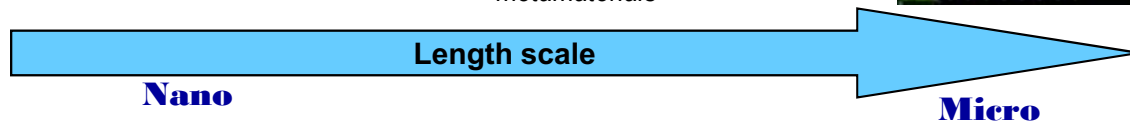
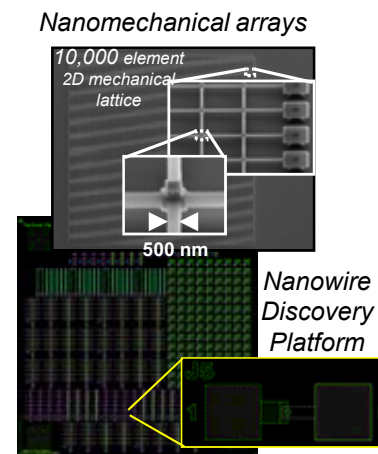
## Nanoscale building blocks



## Fabrication & assembly



## Functional composites & systems



Establishing the fundamental principles that underpin the integration of nanomaterials is of paramount importance to nanoscience and ultimately nanotechnology.

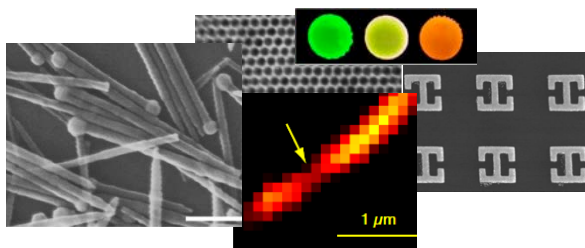




# Science Thrusts: The Foundation of Our Science and User Programs

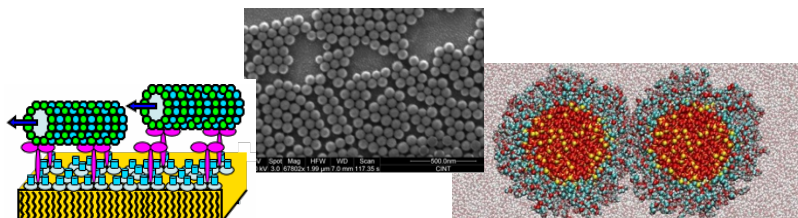
## Nanophotonics & Optical Nanomaterials (NPON)

Synthesis, excitation and energy transformations of optically active nanomaterials



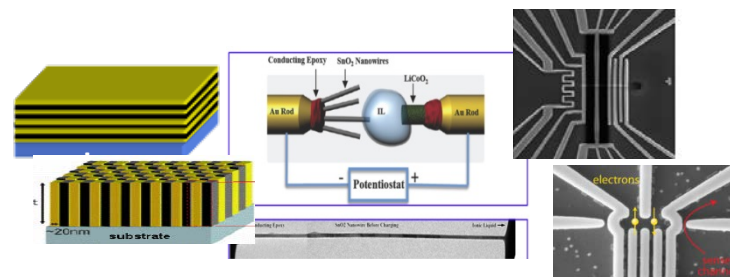
## Soft, Biological, & Composite Nanomaterials (SBCN)

Solution-based nanomaterials synthesis and assembly of soft, composite and artificial biomimetic nanosystems



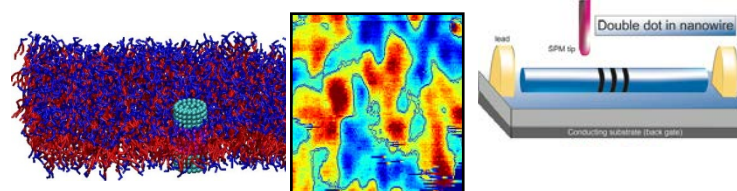
## Nanoscale Electronics & Mechanics (NEM)

Control of electronic transport, wavefunction, and mechanical coupling using nanomaterials



## Theory & Simulation of Nanoscale Phenomena (TSNP)

Assembly, interfacial interactions, and emergent properties of nanoscale systems

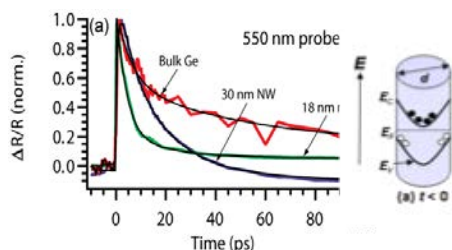




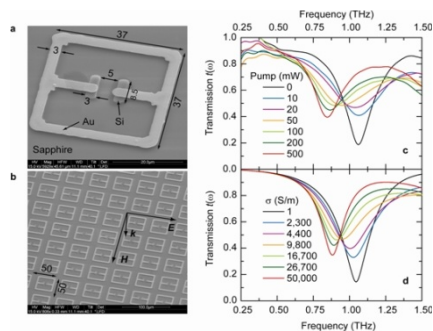
# CINT Special Strengths

## Ultrafast photonics

### Carrier Dynamics

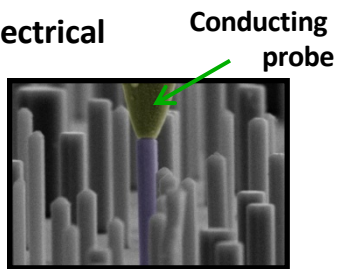


### THz Metamaterials

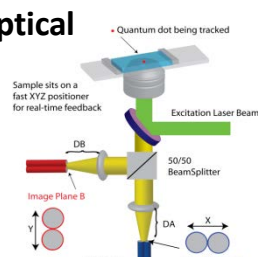


## Nano-manipulation & scanning probes

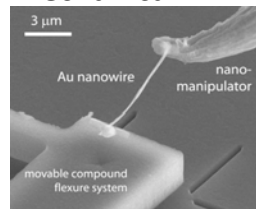
### Electrical



### Optical



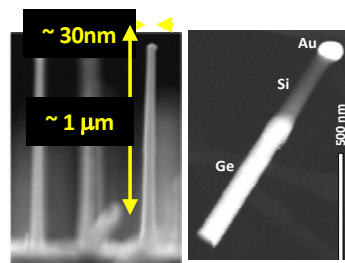
### Mechanical



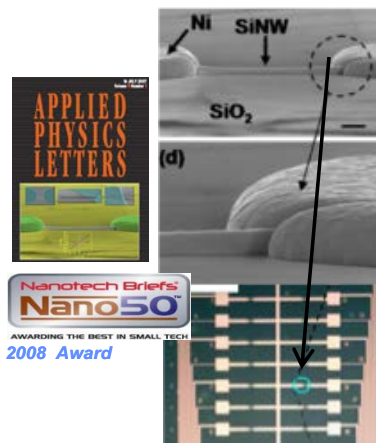
CINT user  
C. Volkert

## Nanofabrication

### Synthesis

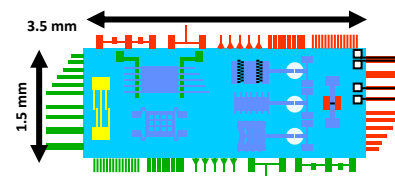


### Directed Assembly

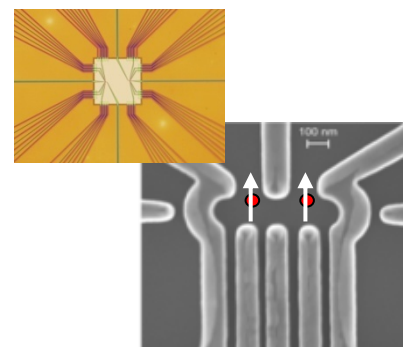


## Discovery Platforms™ (Microsystems to interrogate nanomaterials)

### Cantilever Array platform



### Quantum Computing Transport platform



# Acknowledgements

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Y. Lin, P. Shukla, M. Jain, H. Luo, G. Zou, S. A. Baily, Y. Y. Zhang, N. Haberkorn,  
G. Collis, F. Ronning, A. Mueller, N. A. Mara, L. A. Civale, A. K. Burrell,  
T. M. McCleskey, E. Bauer, and M. E. Hawley








Los Alamos National Laboratory, Los Alamos, NM 87545

J. H. Lee, L. Chen, C. Y. Chou, Z. Bi, X. H. Zhang, and H. Wang

Texas A&M University, College Station, TX 77843








# Outline

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-  Introduction
-  Experimental details and results
  -  Metal-oxide films
  -  Metal-nitride films
  -  Metal-carbide films
  -  Other coatings
-  Summary

# Outline

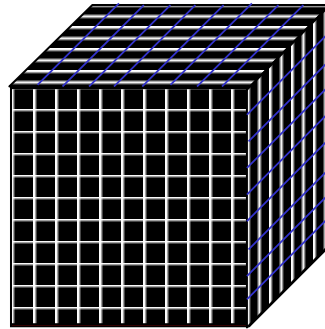
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# Flexibility of Thin Films: Architectures and Functionalities

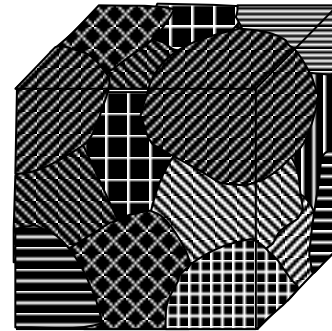
## ➤ Single crystals

- ✓ Intrinsic properties
- Control, size, and availability



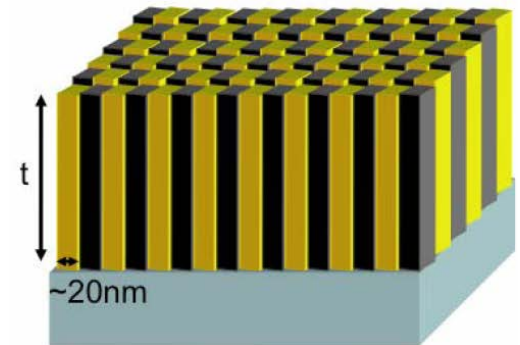
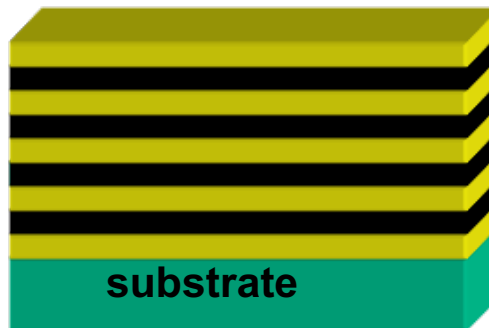
## ➤ Ceramics

- ✓ Easy process
- Grain boundaries & impurities



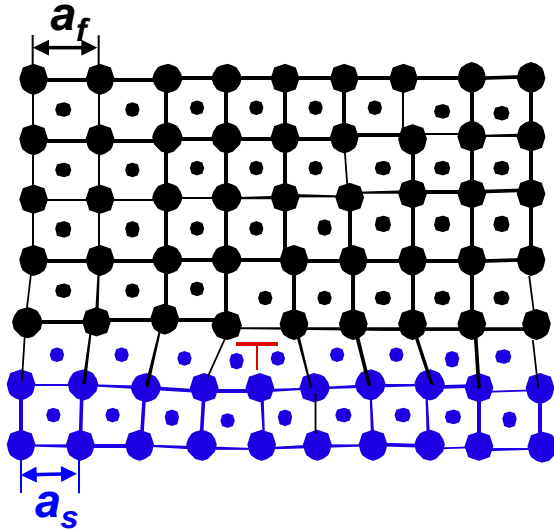
## ➤ Thin films

- ✓ Artificial architectures and microstructures
- ✓ Controlled dimensionalities
- ✓ Growth at far-from or near equilibrium conditions
  - Metastable phases
  - Lattice strain
  - Anisotropy
- Complexities





# Advantages of Epitaxial Thin Films



$$f = \frac{(a_f - a_s)}{(a_f + a_s)/2} \approx \frac{a_f - a_s}{a_s}$$

- When the lattice mismatch is large, strain can be partially relaxed through misfit dislocations.
- When the lattice mismatch is small, the film can be strained.

- Single-crystal not available
- Grainboundary in polycrystalline films
- Locking-in the crystal structure, and so the phases
- Induced preferential orientation
- Well controlled properties

# Different Techniques Available for Growth of Thin Films

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## Physical vapor deposition (**PVD**)

- Sputtering, e-beam evaporation, molecular beam epitaxy, pulsed laser deposition

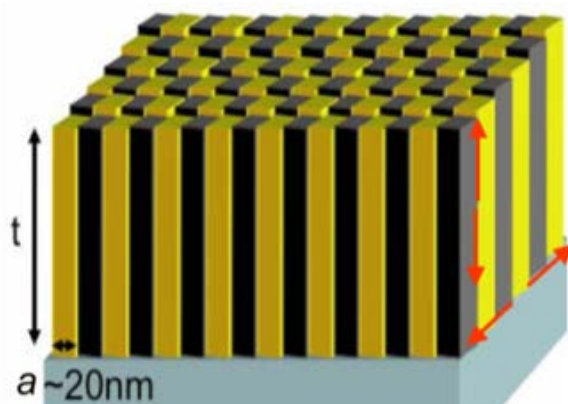
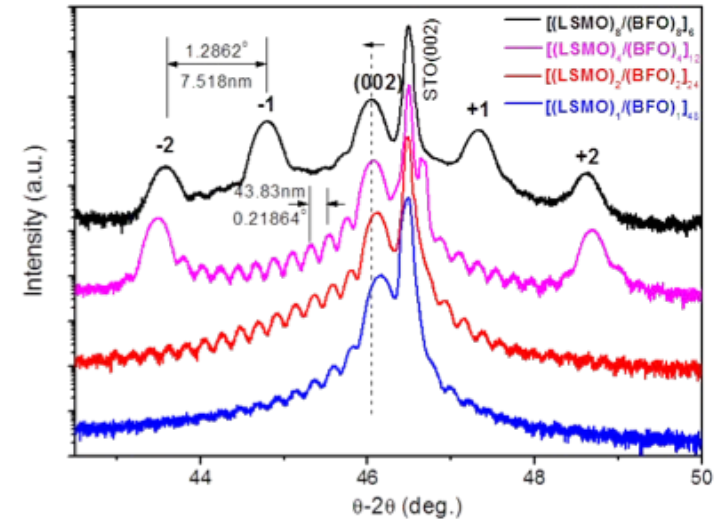
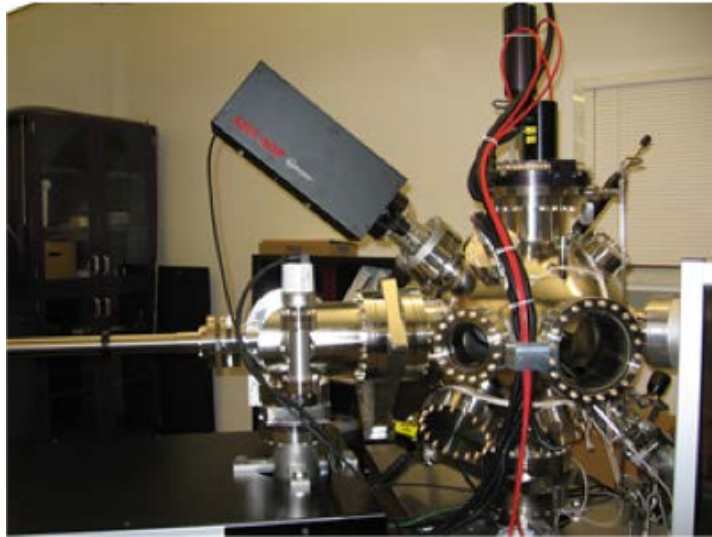
## Chemical vapor deposition (**CVD**)

- Plasma-enhanced CVD, low pressure CVD, metal-organic CVD

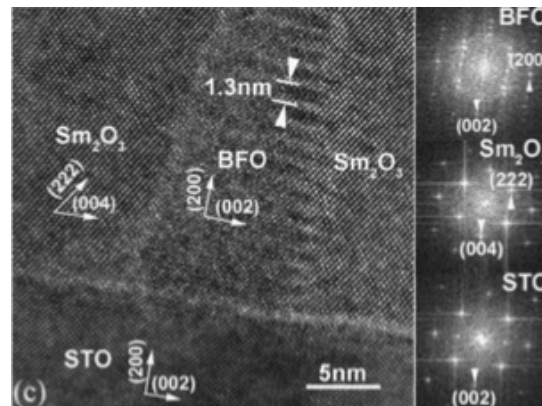
## Chemical solution deposition (**CSD**)

- Sol-gel, metal-organic decomposition (MOD)

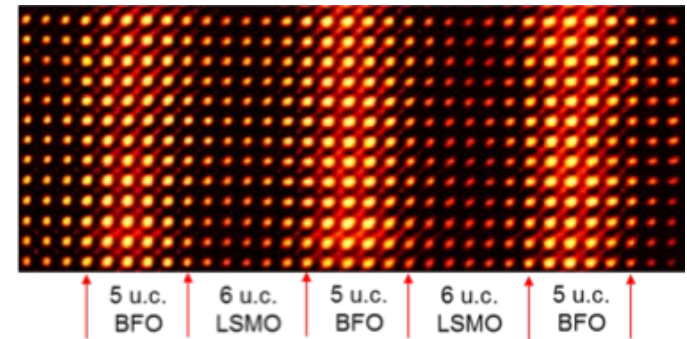
# PVD – A Powerful Technique to Synthesize Films over Multiple Length Scales



*Nat. Mater.* 7, 314 (2008).



*Adv. Mater.* 21, 3794 (2009).



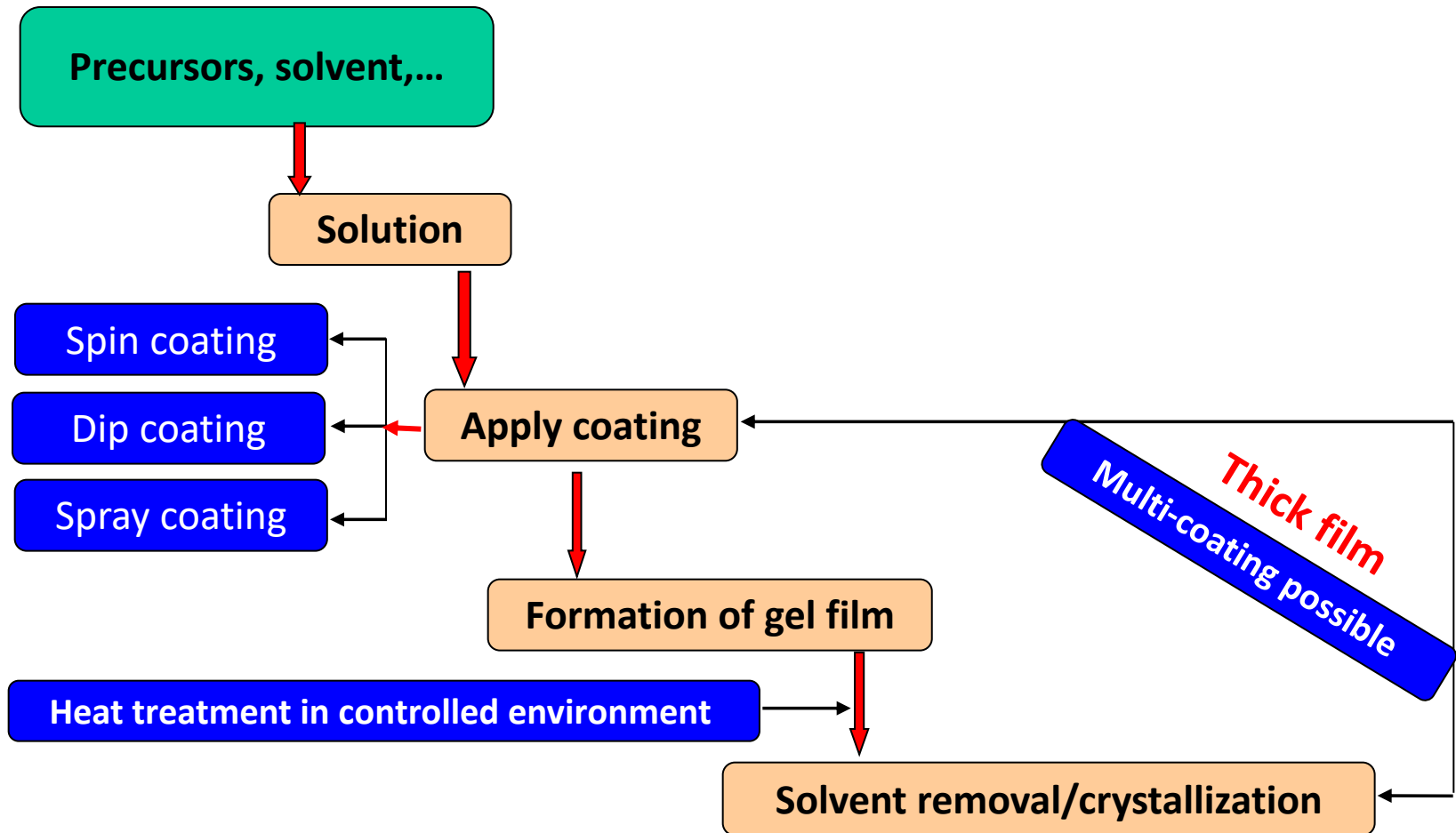
# CSD – Low Cost, Easy Setup, and Coating on Irregular Surfaces



- Spin-coating
- Dip-coating
- Printing
- Painting



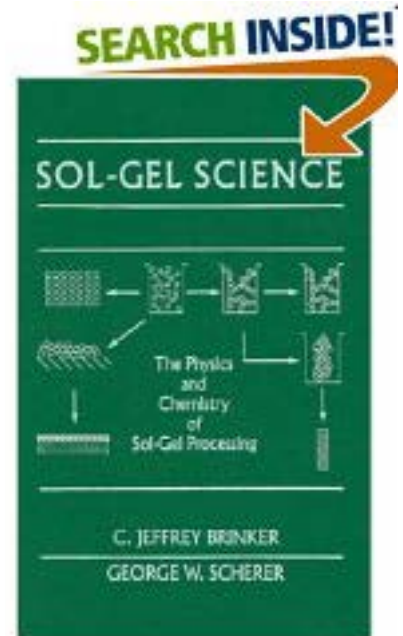
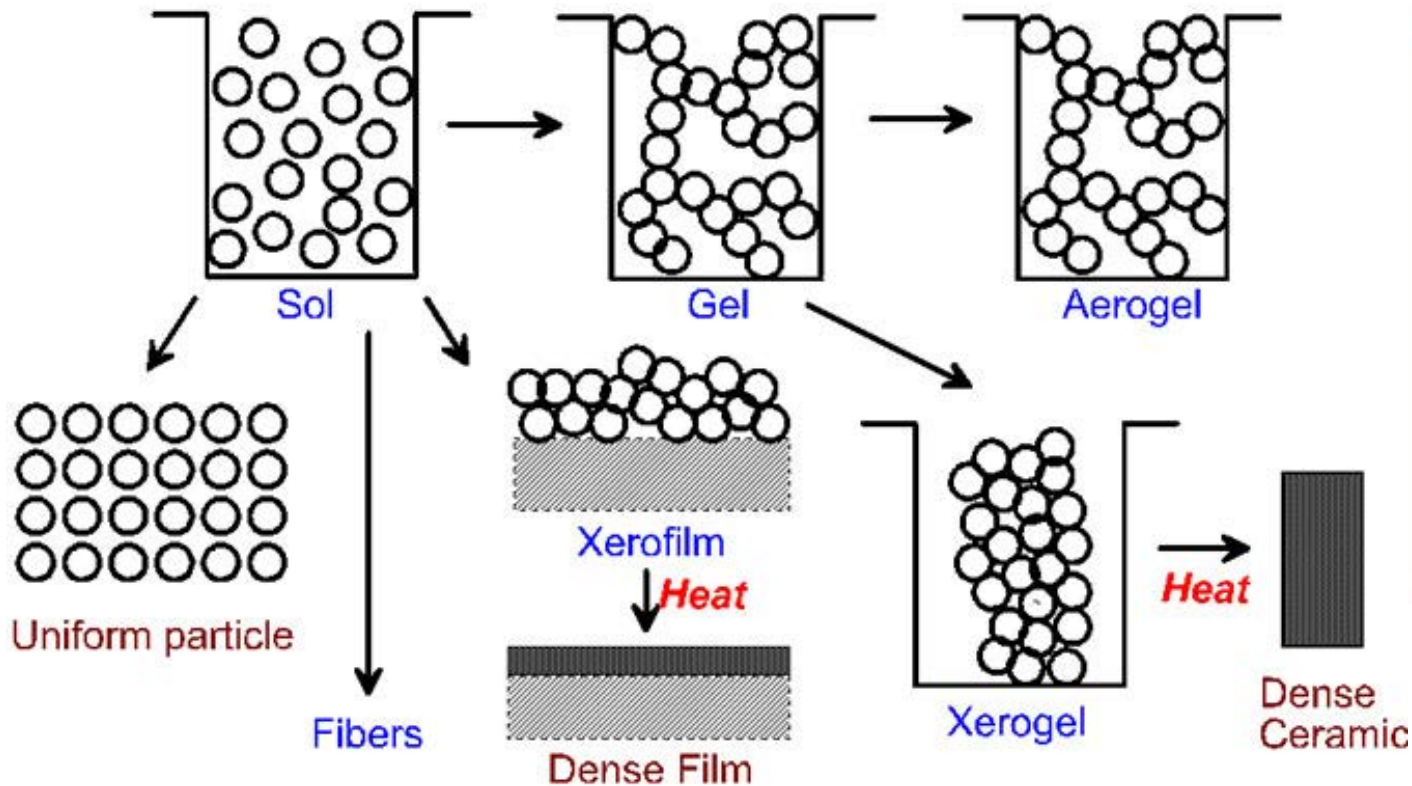
# Flow Chart of Typical Chemical Solution Deposition Process





# Chemical Solution Deposition: Sol-Gel Process








## Overview of the sol-gel process





# Outline

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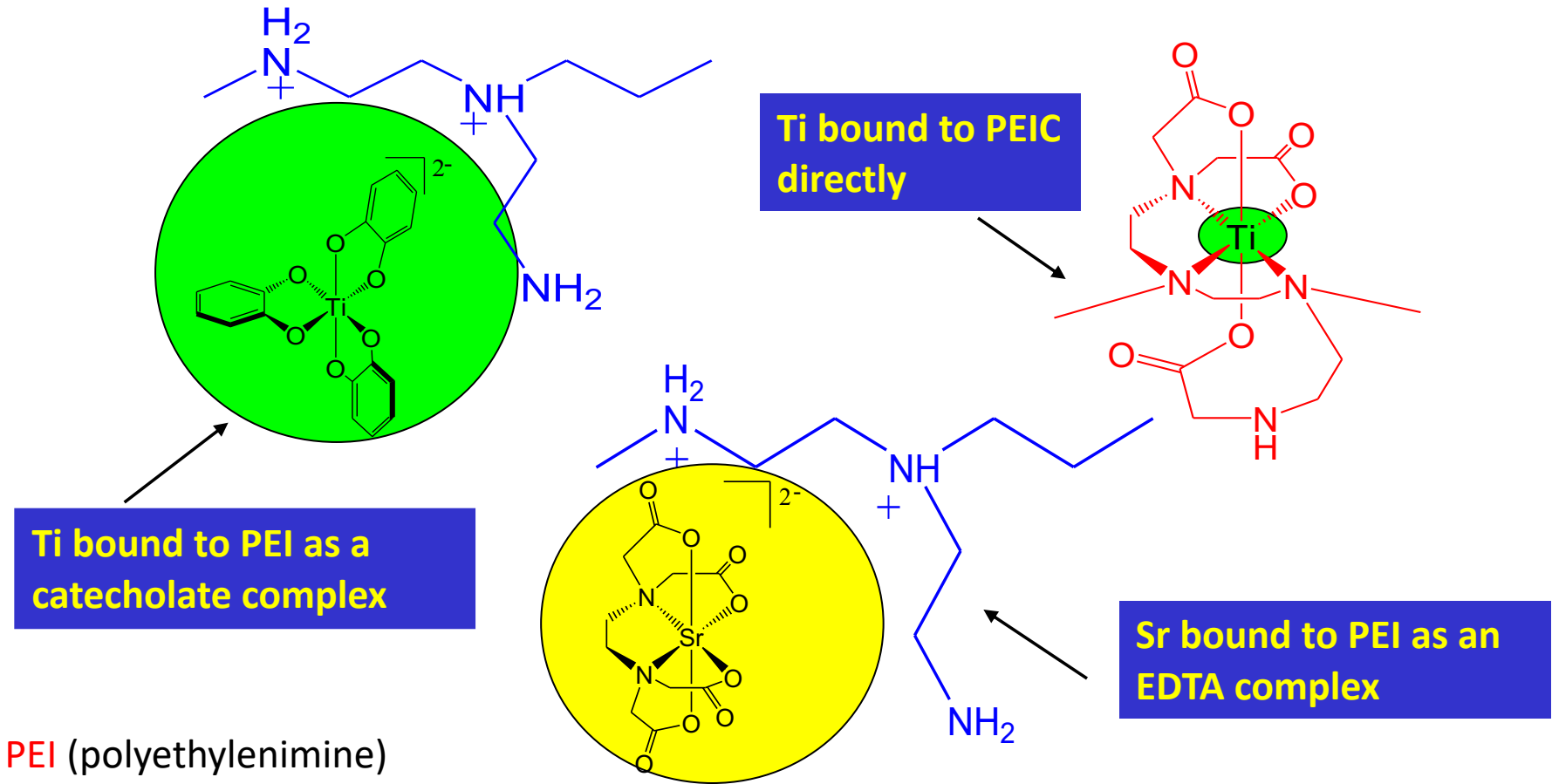
-  Introduction
-  Experimental details and results
  -  Metal-oxide films
  -  Metal-nitride films
  -  Metal-carbide films
  -  Other coatings
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# PAD: Polymer-Assisted Deposition

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- ☞ A chemical solution technique to deposit films – by mixing metal salts with water-soluble polymers
- ☞ Critical roles of polymers
  - The polymer effectively binds the metal ions
    - ☞ to stabilize the metal ions from hydrolysis in water
    - ☞ to control the solution stability, reactivity, and processability
    - ☞ to enable filtration for the growth of high quality epitaxial complex materials
- ☞ Advantages
  - By binding metal ions to a polymer that has regular ligand sites, thin films can be deposited in a homogeneous manner.

# Schematic Illustration of Metals as Simple Salts or Complexes Bound to Polymers



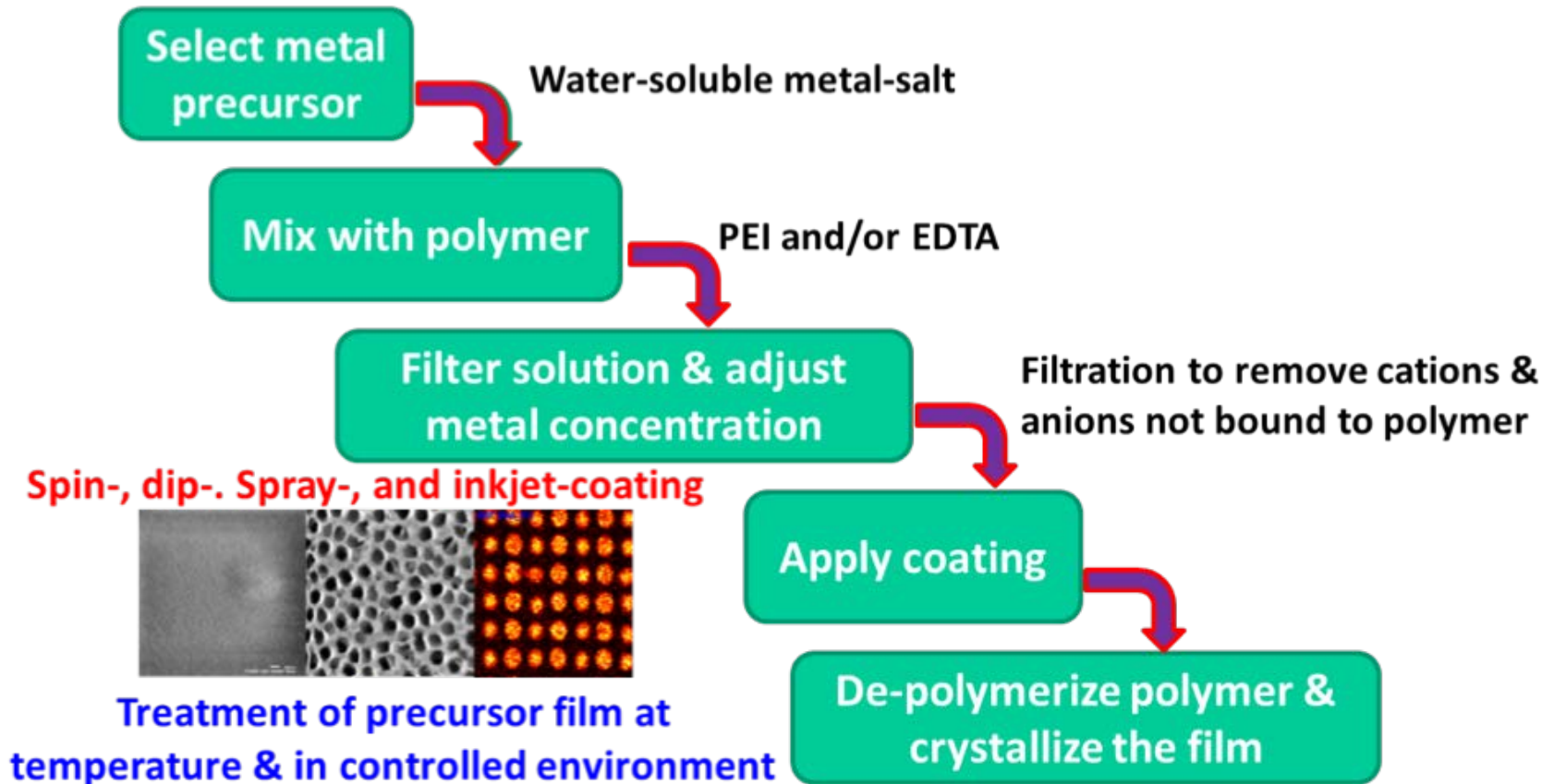
PEI (polyethylenimine)

PEIC (carboxylated-polyethylenimine)

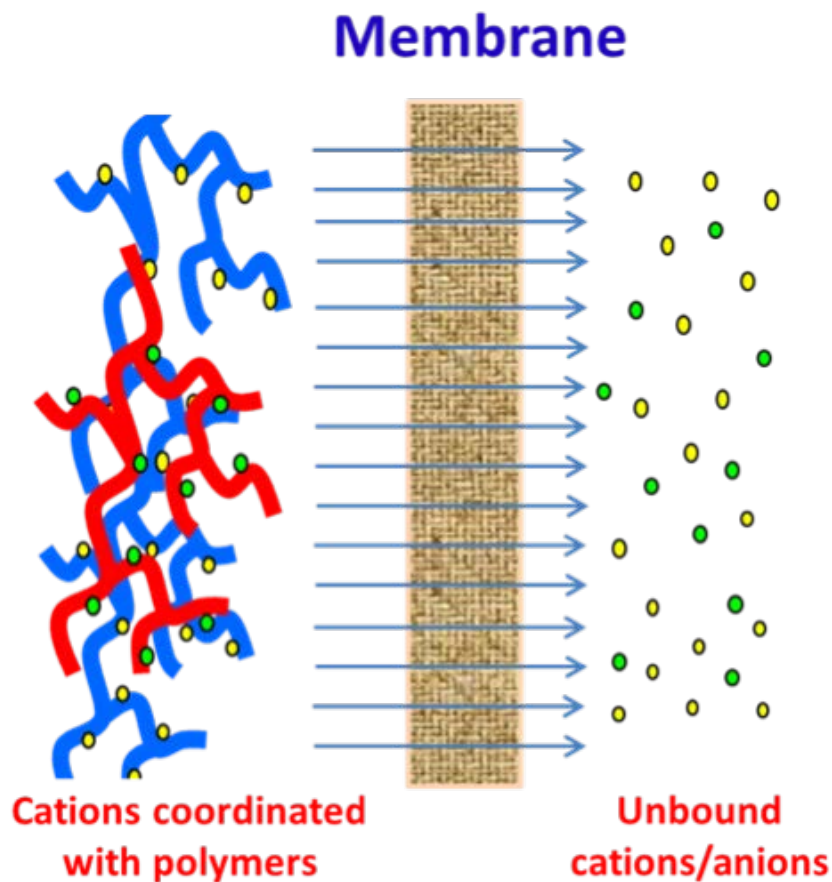
EDTA (ethylenediaminetetra-aceticacid)

# PAD Process

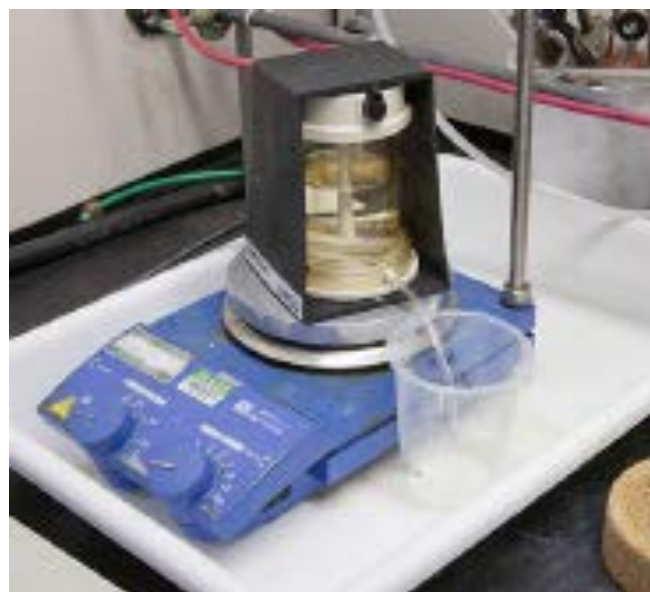
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# Filtration Critical for Growth of Epitaxial Complex Films



*Chem. Soc. Rev.* 43, 2141 (2014).



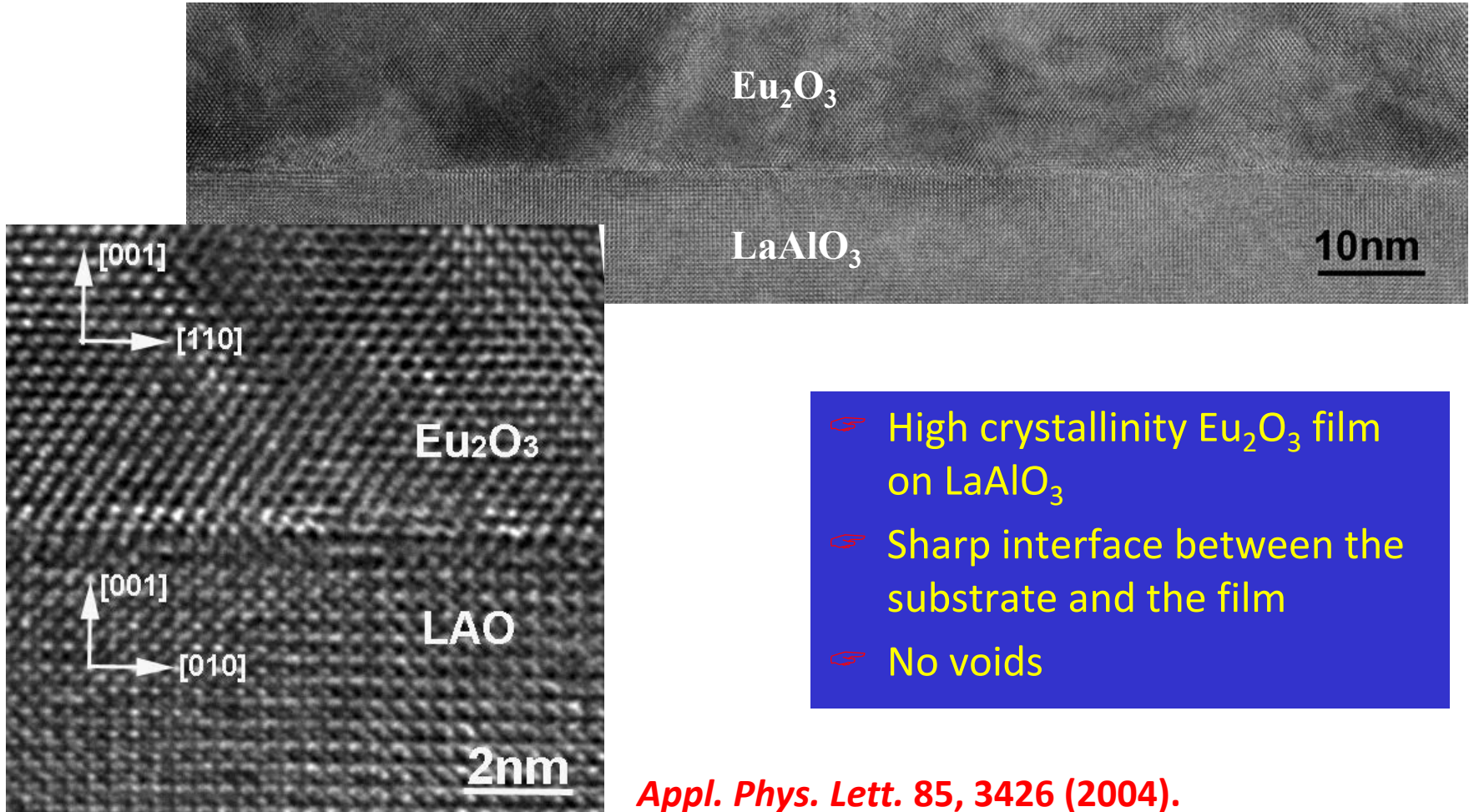
# Elements Coordinated with Polymers to Form Stable Precursor Solutions

IA																	VIIIA
H	IIA											IIIA	IVA	VA	VIA	VIIA	He
Li	Be											B	C	N	O	F	Ne
Na	Mg	IIIB	IVB	VB	VIB	VII B	VIII B		IB	IIB							
K	Ca	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	Ga	Ge	As	Se	Br	Kr
Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	In	Sn	Sb	Te	I	Xe
Cs	Ba	†	Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Tl	Pb	Bi	Po	At	Rn
Fr	Ra	‡	Rf	Db	Sg	Bh	Hs	Mt	Ds	Rg	Cn						
		†	La	Ce	Pr	Nd	Pm	Sm	Eu	Gd	Tb	Dy	Ho	Er	Tm	Yb	Lu
		‡	Ac	Th	Pa	U	Np	Pu	Am	Cm	Bk	Cf	Es	Fm	Md	No	Lr

*Chem. Soc. Rev.* 42, 439 (2013).



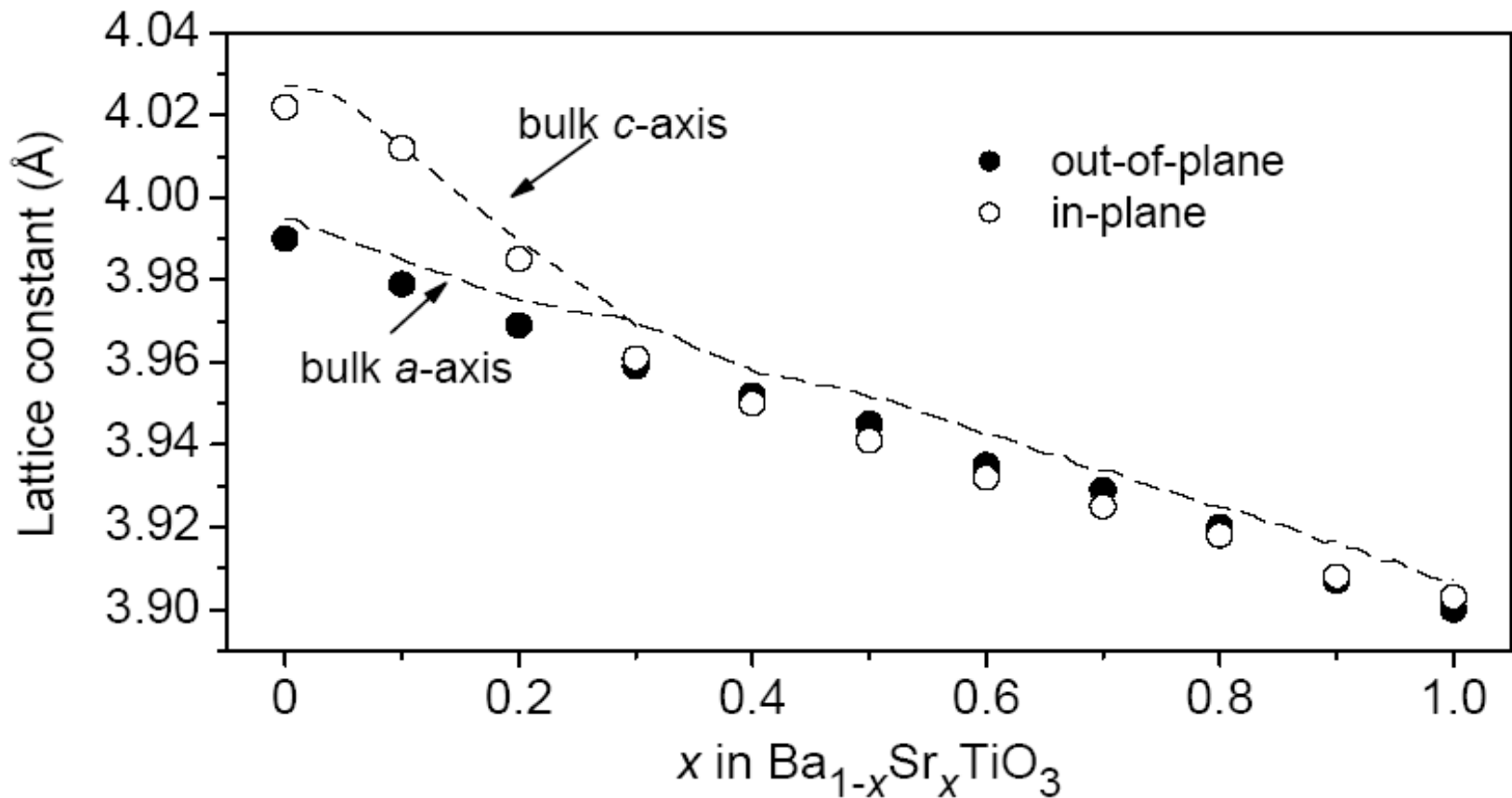
# High Quality Epitaxial Simple Metal-oxide Films as Evidenced by the Dense Film and Sharp Interface



- High crystallinity  $\text{Eu}_2\text{O}_3$  film on  $\text{LaAlO}_3$
- Sharp interface between the substrate and the film
- No voids

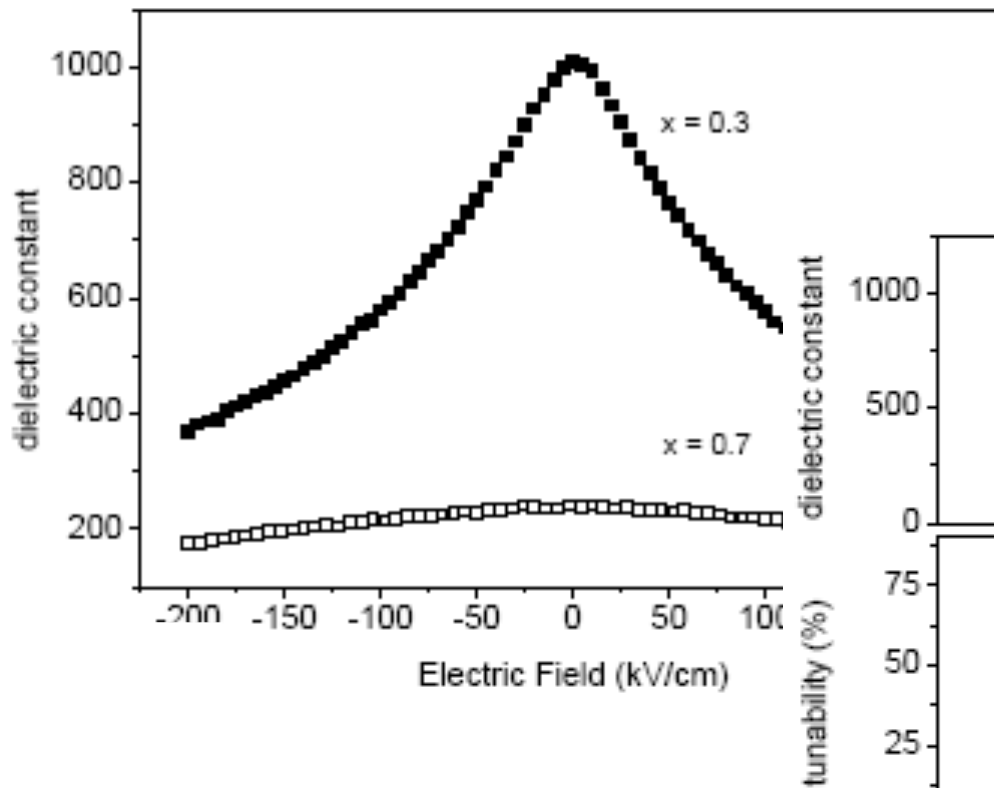
*Appl. Phys. Lett.* 85, 3426 (2004).

# Lattice Parameters of $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$ as A Function of Ba/Sr Ratios

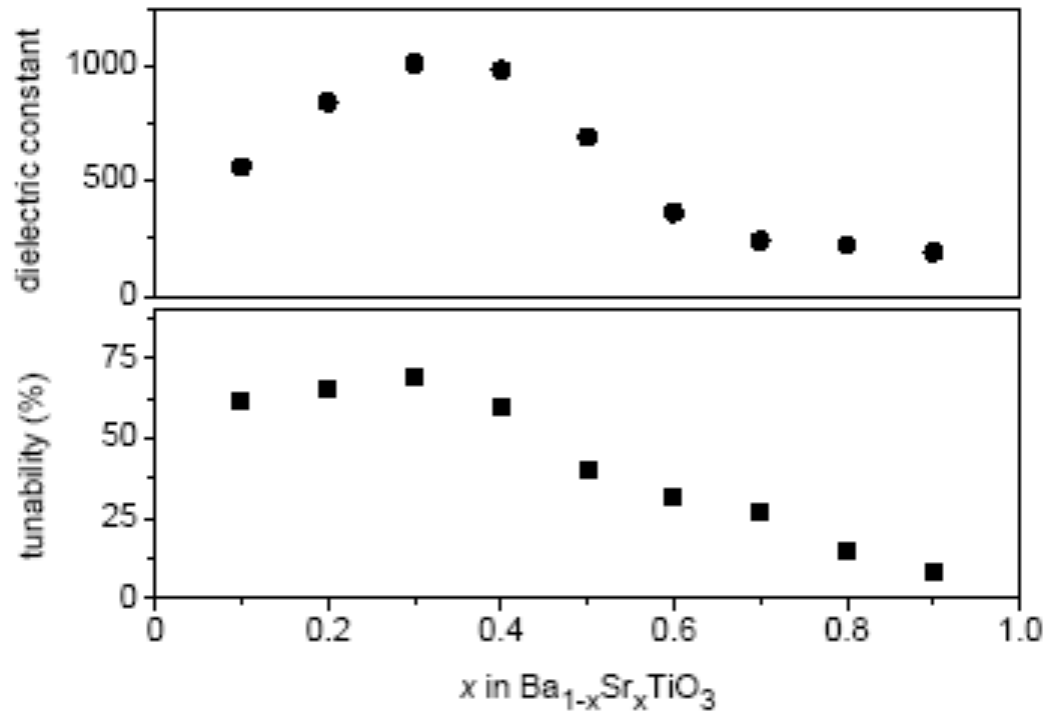


*Appl. Phys. Lett.* 85, 5007 (2004).

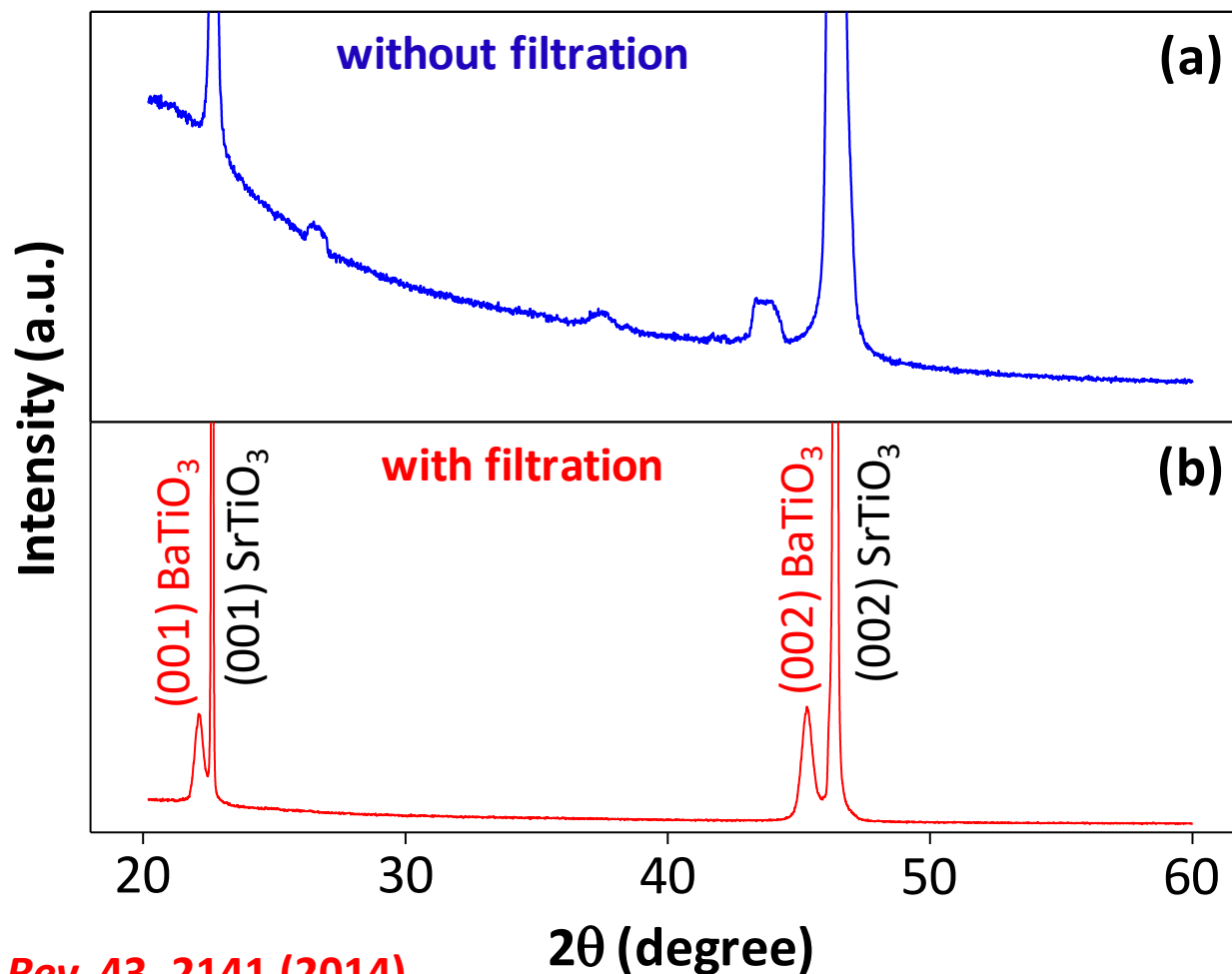
# Dielectric Properties of $\text{Ba}_{1-x}\text{Sr}_x\text{TiO}_3$ Films as A Function of Ba/Sr Ratios



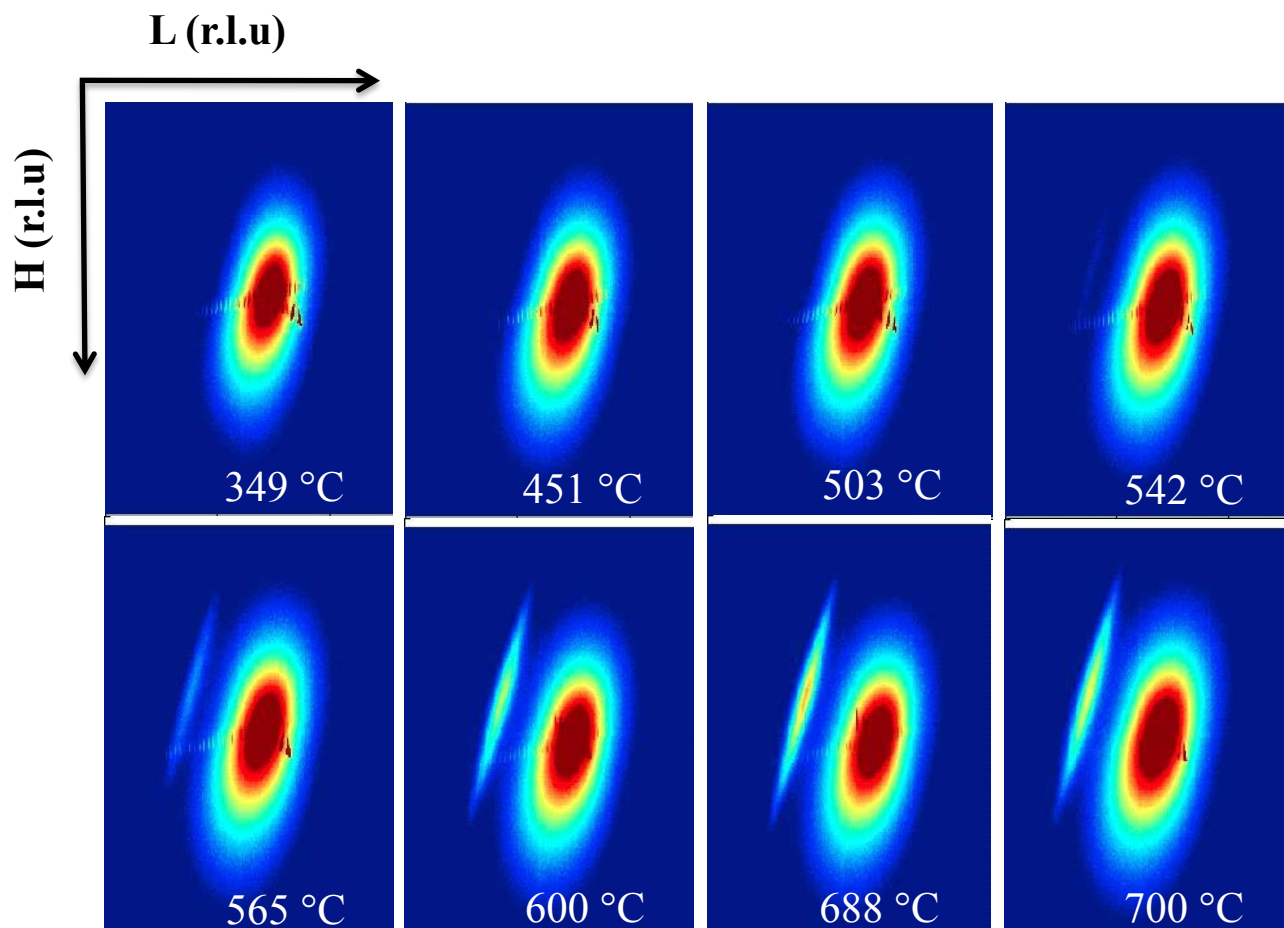
$$\text{Tunability} = T(\%) = 100 \times \frac{C_0 - C_V}{C_0}$$



# Filtration Critical for Growth of Epitaxial Complex Metal Oxide Films

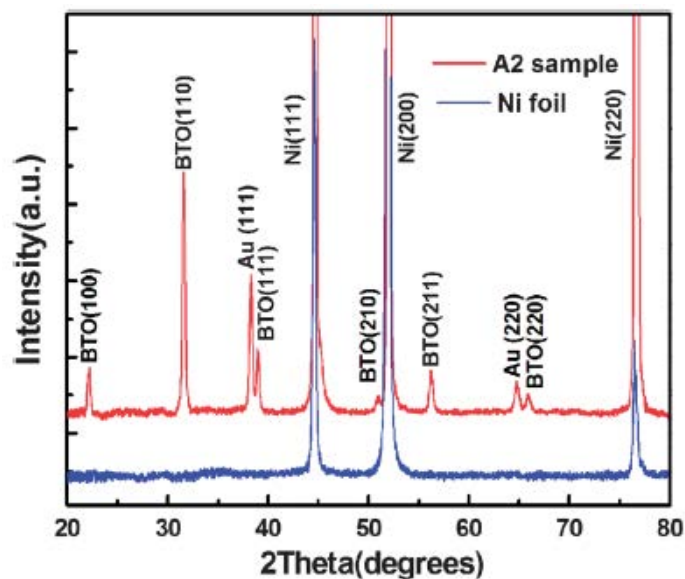


# Filtration Critical for Growth of Epitaxial Complex Metal Oxide Films

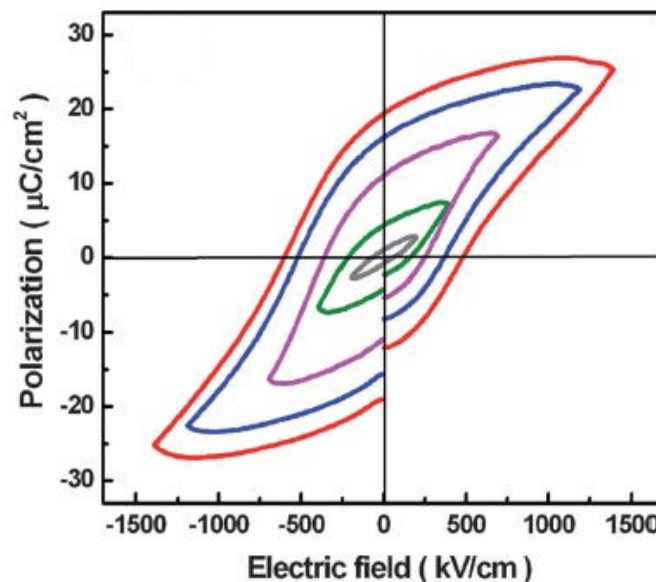


*Chem. Soc. Rev.* **43**, 2141 (2014).

# BaTiO<sub>3</sub> Films Deposited on Polycrystalline Ni Substrates



Ni: 0.5 mm  
BTO: 500 nm



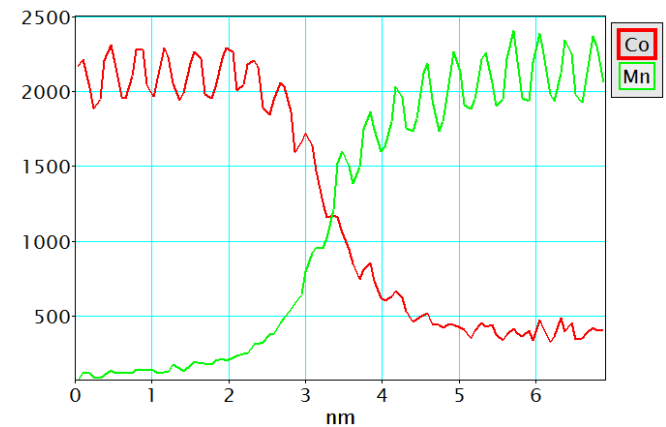
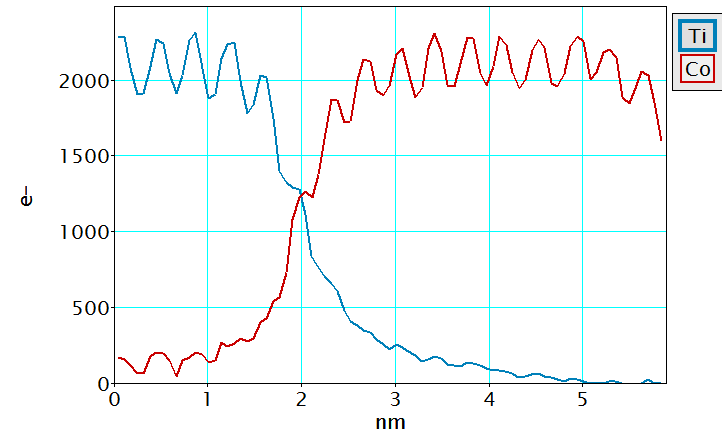
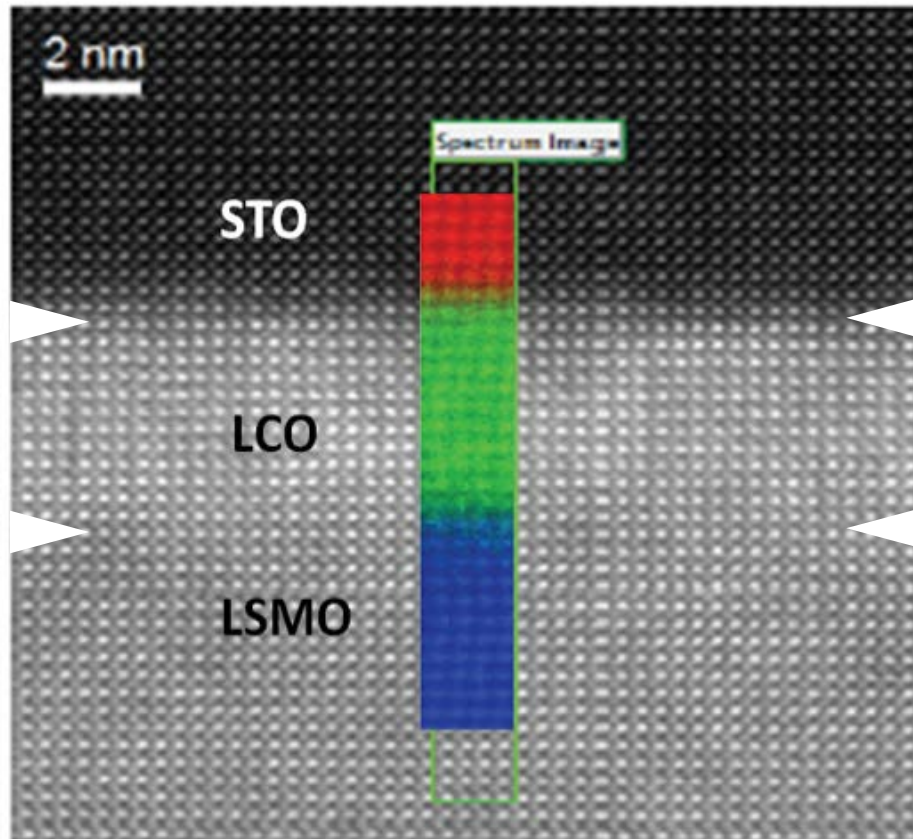
Typical XRD  $\theta$ - $2\theta$  patterns of as-grown BaTiO<sub>3</sub> film on polycrystalline Ni

Polarization of a BaTiO<sub>3</sub> film as a function of the electric field at room temperature

*J. Mater. Chem. C* 2, 708 (2014).

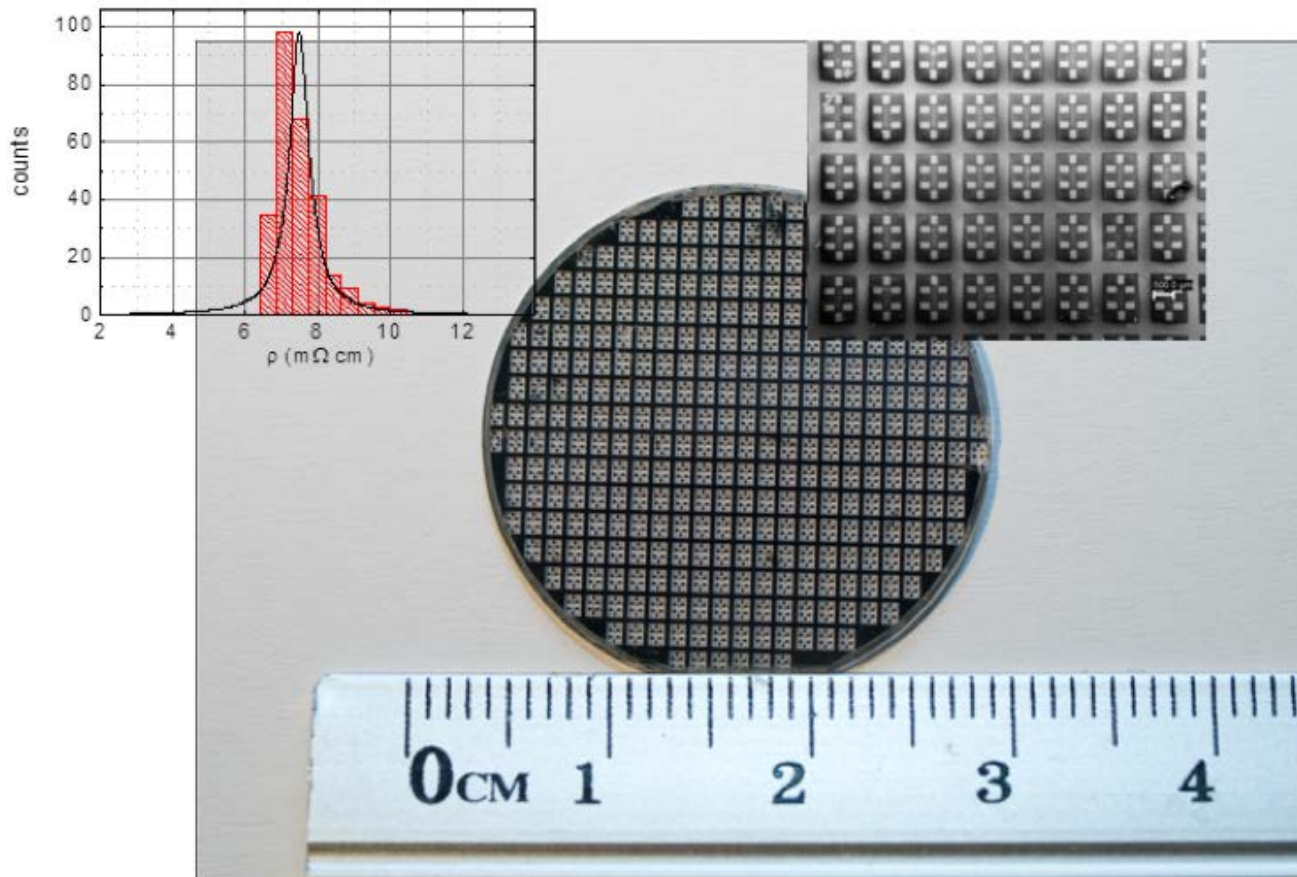


# Epitaxial Growth of $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3/\text{LaCoO}_3$ on $\text{SrTiO}_3$ by PAD



By F. Rivadulla, Universidad de Santiago de Compostela, Spain

# Uniform Deposition of Epitaxial Complex Metal Oxide Films by PAD



$\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$   
18 nm

By F. Rivadulla, Universidad de Santiago de Compostela, Spain

# Polymer-assisted deposition of metal-oxide films

Q. X. JIA<sup>1\*</sup>, T. M. MCCLESKEY<sup>2</sup>, A. K. BURRELL<sup>2</sup>, Y. LIN<sup>1</sup>, G. E. COLLIS<sup>2</sup>, H. WANG<sup>1</sup>, A. D. Q. LI<sup>3</sup>  
AND S. R. FOLTYN<sup>1</sup>

<sup>1</sup>Superconductivity Technology Center, Division of Materials Science and Technology, and <sup>2</sup>Structural and Inorganic Chemistry, Division of Chemistry, Los Alamos National Laboratory, Los Alamos, New Mexico 87545, USA

<sup>3</sup>Department of Chemistry, Washington State University, Pullman, Washington 99164, USA

\*e-mail: qxjia@lanl.gov

Appl. Phys. Lett. 99, 083113 (2011); doi:10.1063/1.3629993 (3 pages)

## Magnetoresistance in epitaxial thin films of $\text{La}_{0.85}\text{Ag}_{0.15}\text{MnO}_3$ produced by polymer assisted deposition

R. Cobas<sup>1</sup>, S. Muñoz-Perez<sup>1</sup>, J. M. Cadogan<sup>1</sup>, T. Puig<sup>2</sup>, and X. Obradors<sup>2</sup>

<sup>1</sup>Department of Physics and Astronomy, University of Manitoba, Winnipeg, R3T 2N2 Manitoba, Canada

<sup>2</sup>Institut de Ciència dels Materials de Barcelona, CSIC, Campus de la UAB, 08193 Bellaterra, Spain

*Nature Protocols* 5, 1440 - 1446 (2010)

Published online: 22 July 2010 | doi:10.1038/nprot.2010.105








Subject Category: [Chemical modification](#)

## Polymer-assisted deposition of homogeneous metal oxide films to produce nuclear targets

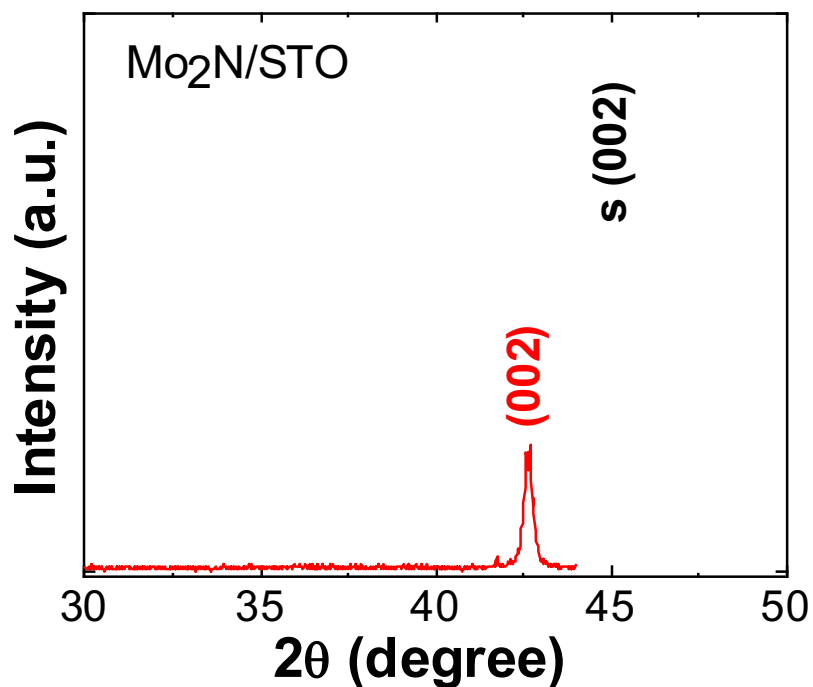
Mazhar N Ali<sup>1,2</sup>, Mitch A Garcia<sup>1,2</sup>, T Parsons-Moss<sup>1,2</sup> & Heino Nitsche<sup>1,2</sup>

# Outline

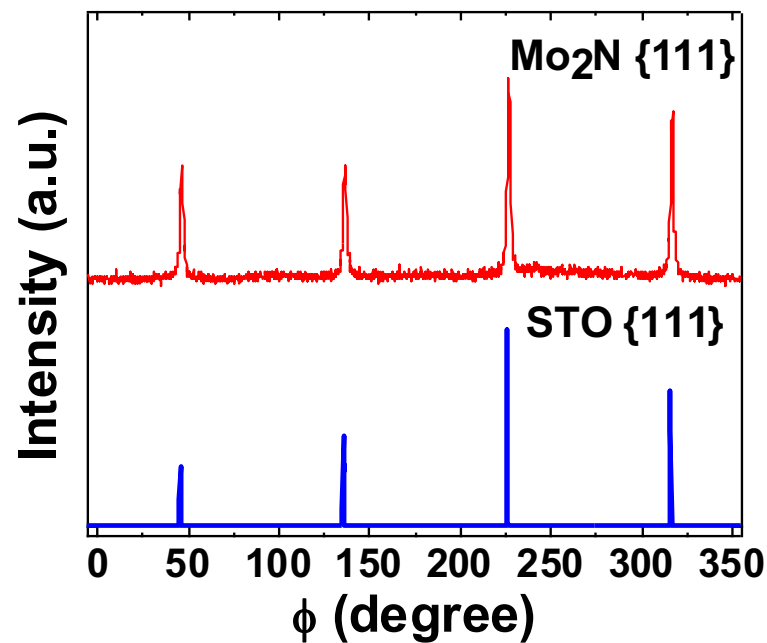
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-  Introduction
-  Experimental details and results
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# Epitaxial Mo<sub>2</sub>N Films on SrTiO<sub>3</sub>

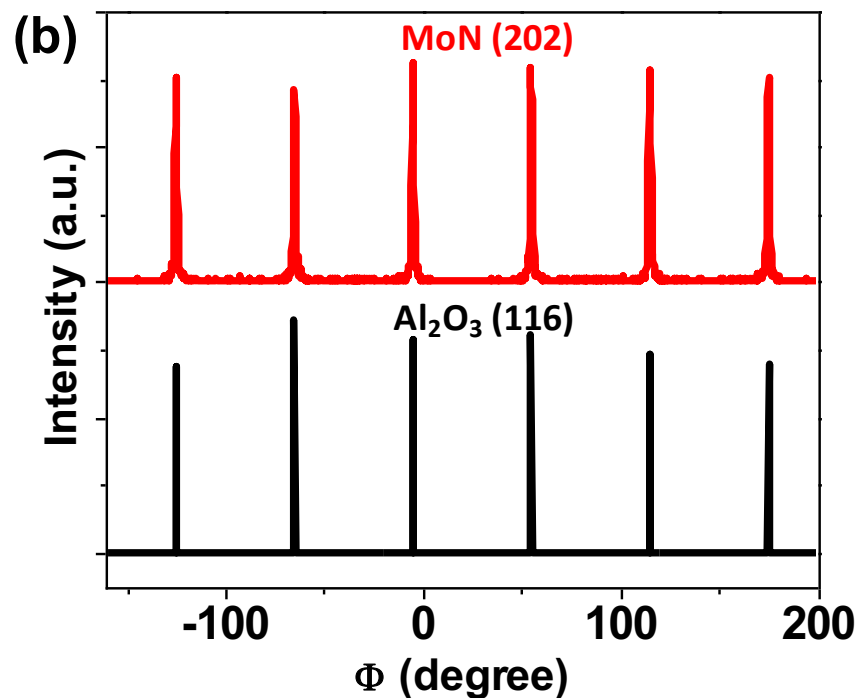
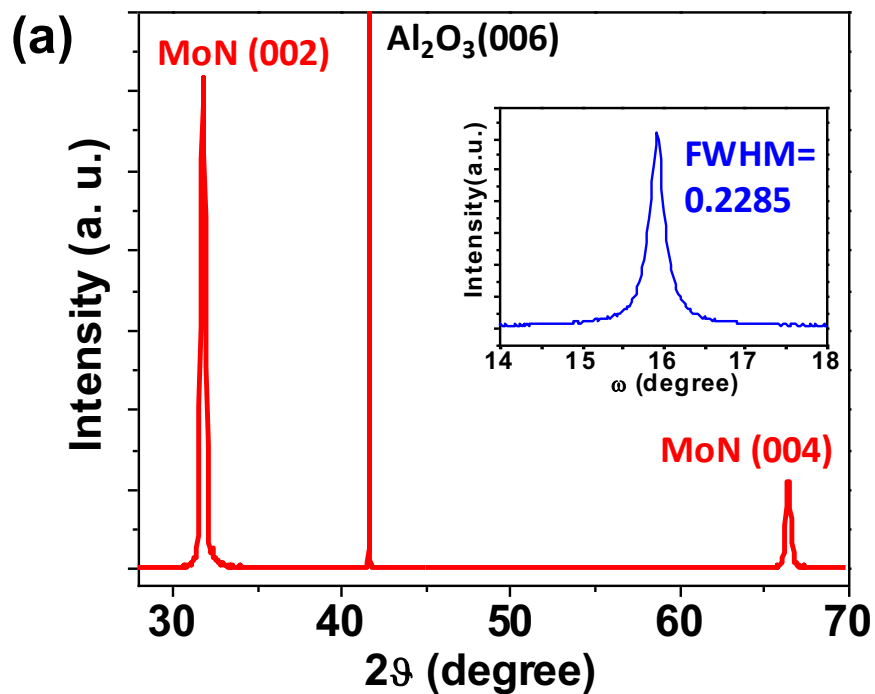


γ - Mo<sub>2</sub>N (cubic)  
 $a = 0.416$  nm



*J. Phys. Chem. C* 115, 17880 (2011).

# Epitaxial MoN Films on c-cut Sapphire



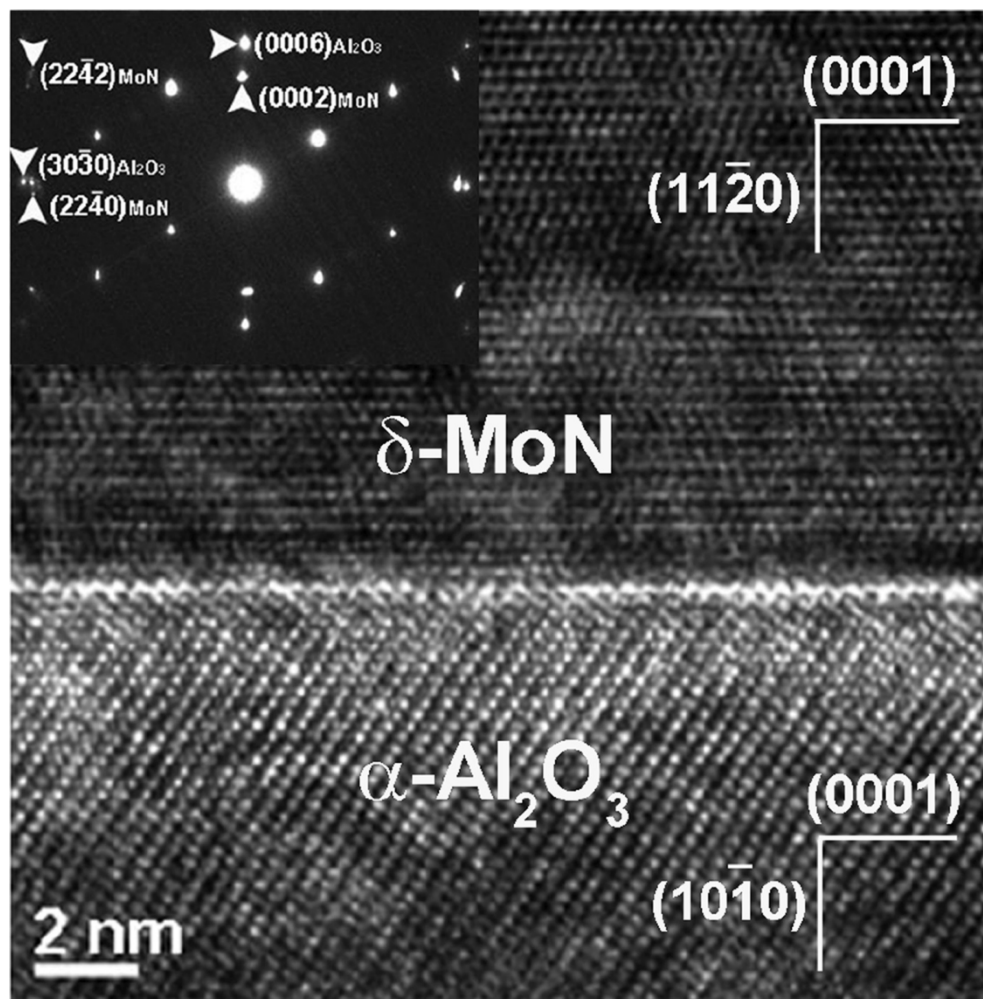
$\delta$ -MoN (hexagonal)

$a = 0.572 \text{ nm}$

$c = 0.562 \text{ nm}$

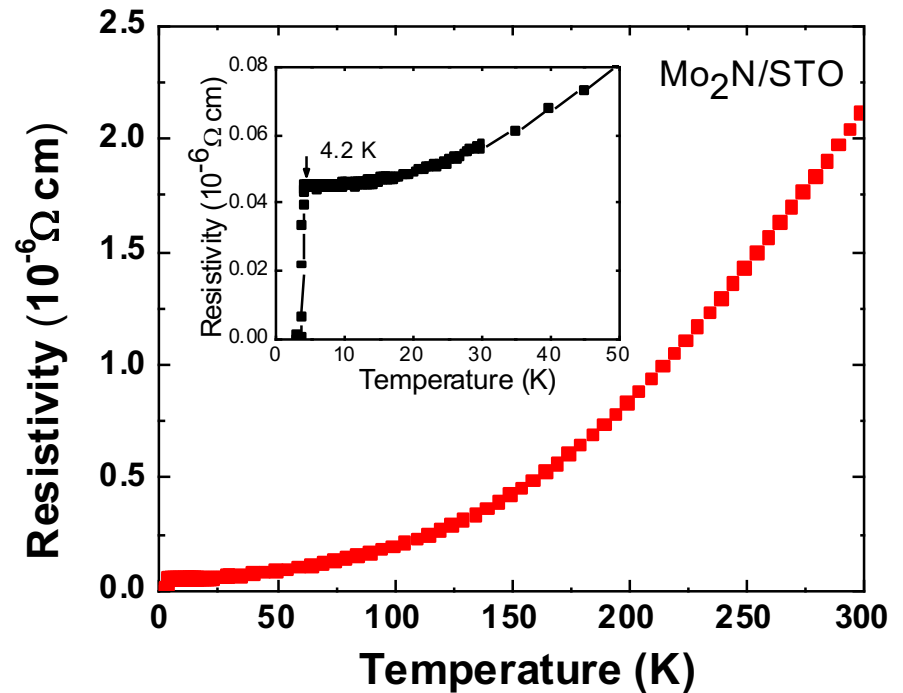
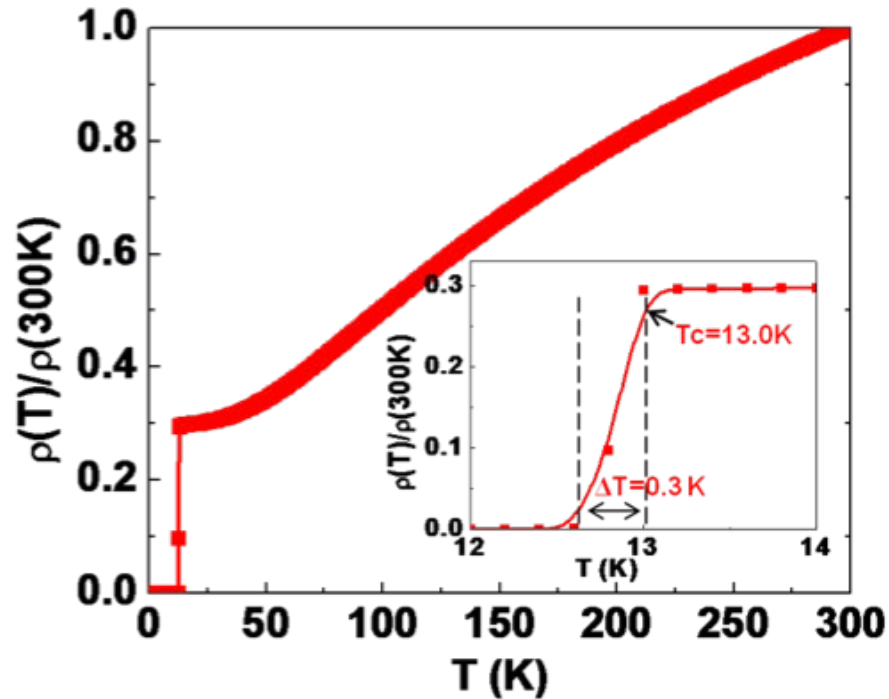


# Sharp Interface between the Substrate and the MoN Film

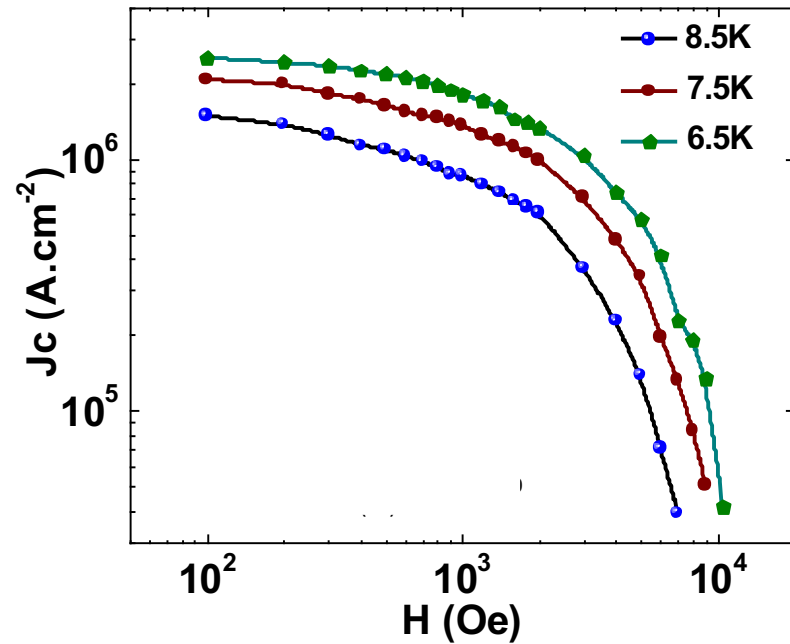
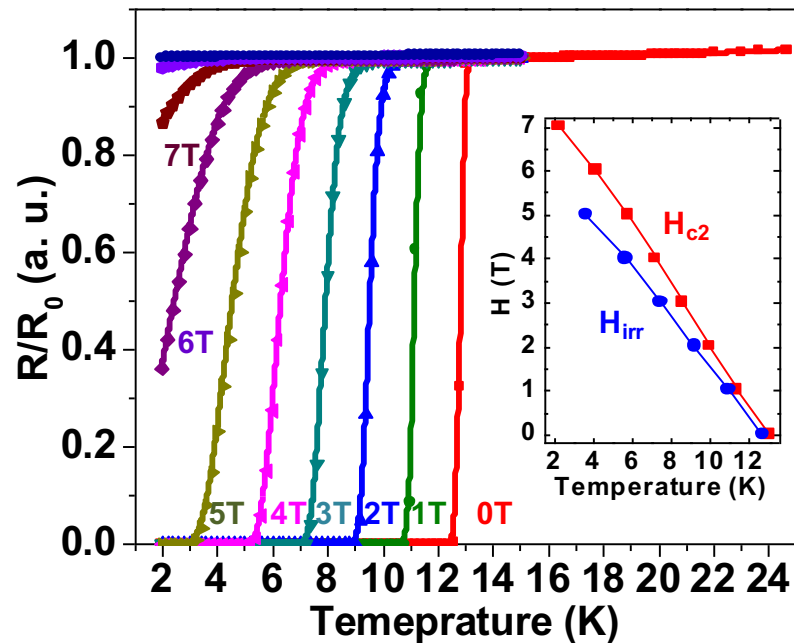


*J. Am. Chem. Soc.*  
133, 20735 (2011).

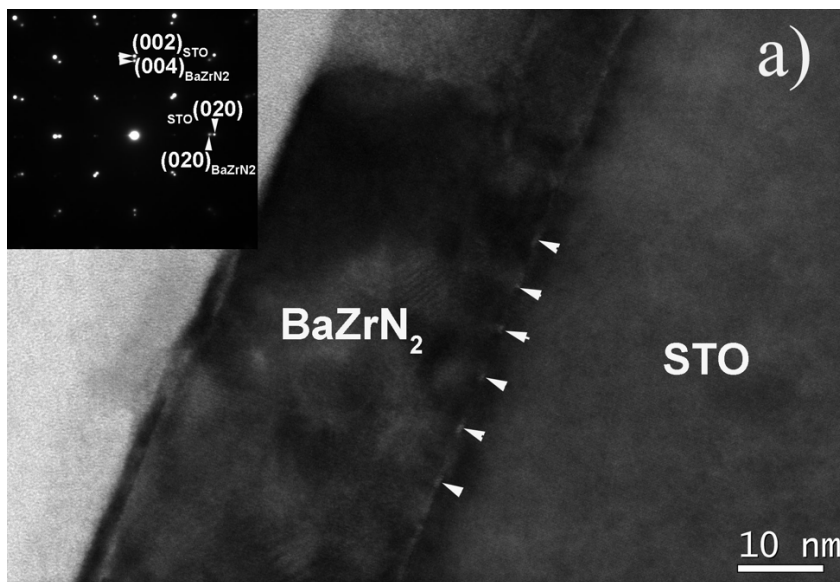
# MoN and Mo<sub>2</sub>N Films with Different Superconducting Properties as Expected



# Superconducting Properties of the MoN Films



# Well Controlled Interface between the Epitaxial $\text{BaZrN}_2$ Film and the Substrate

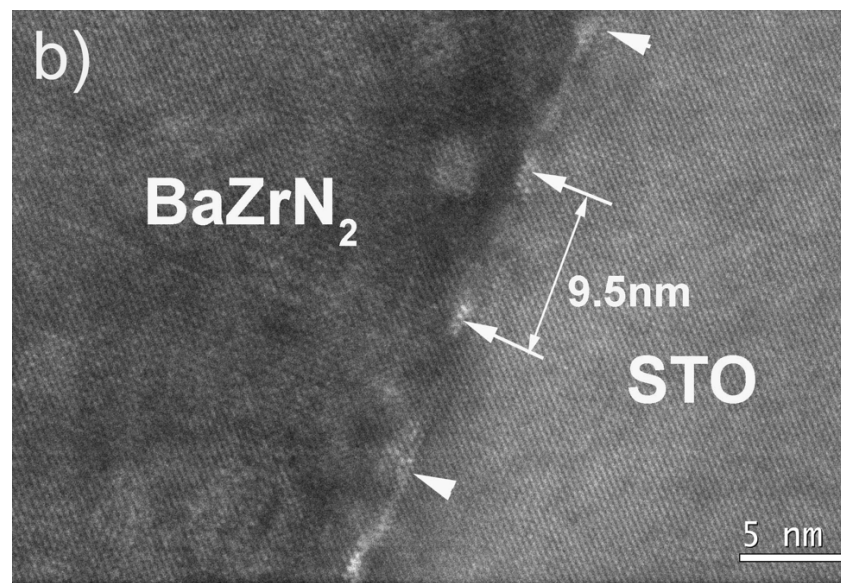


$\text{BaZrN}_2$ :  $a = 4.08 \text{ \AA}$   
 $\text{SrTiO}_3$ :  $a = 3.901 \text{ \AA}$

The lattice misfit: 4.25 %

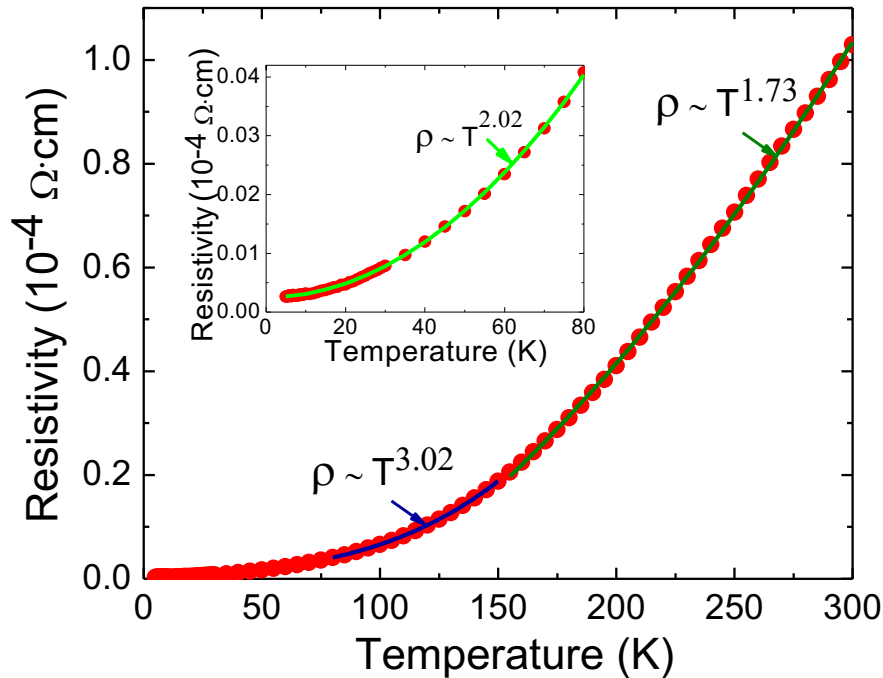
Dislocation spacing  $\sim 9.5 \text{ nm}$

$23 a_{\text{BZN}}$  to  $24 a_{\text{STO}}$



*Angew. Chemie. Int. Ed.* **121**, 1518 (2009).

# Very Large Residual Resistivity Ratio of High Quality BaZrN<sub>2</sub> Films



$$\rho(T) = \rho_0 + AT^m$$

Different conduction mechanisms








- electron-electron scattering (5-80 K)
- electron-phonon scattering (80-155 K)
- disordered localized magnetic moment (160-300 K)

Residual resistivity ratio

$$\text{RRR} = \rho_{300\text{K}} / \rho_{5\text{K}} = 396$$

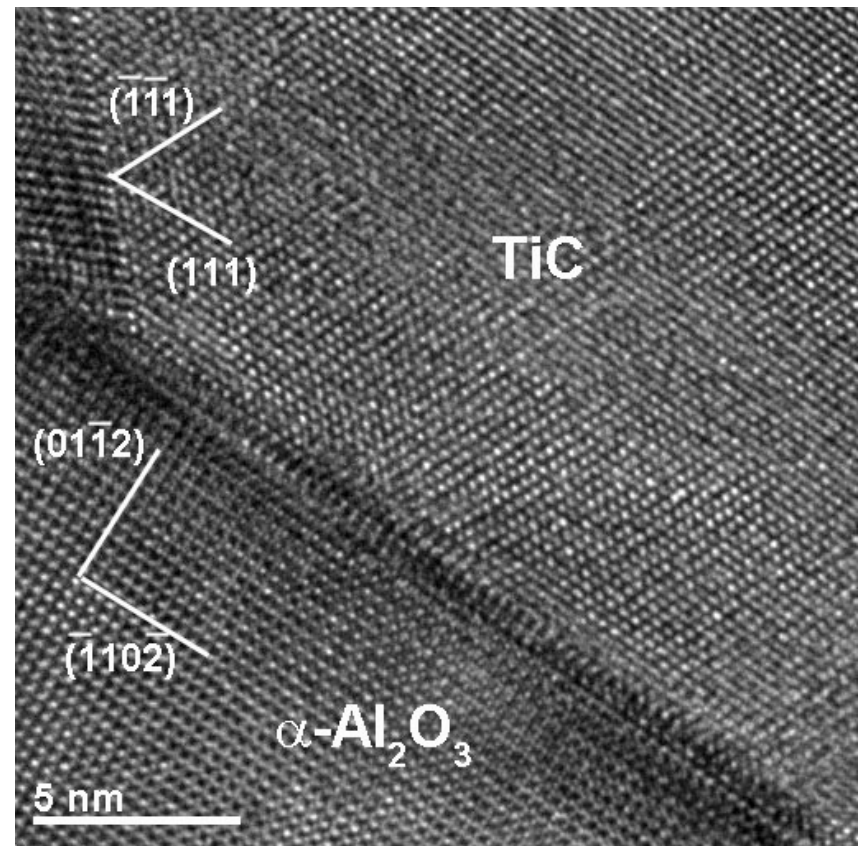
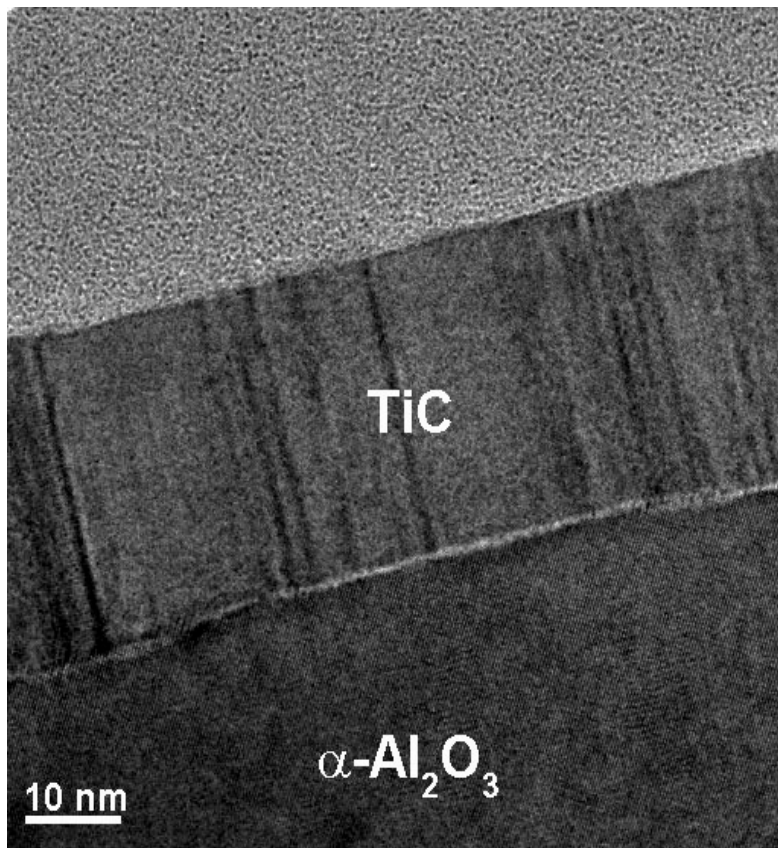
# Outline

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-  Introduction
-  Experimental details and results
  -  Metal-oxide films
  -  Metal-nitride films
  -  Metal-carbide films
  -  Other coatings
-  Summary



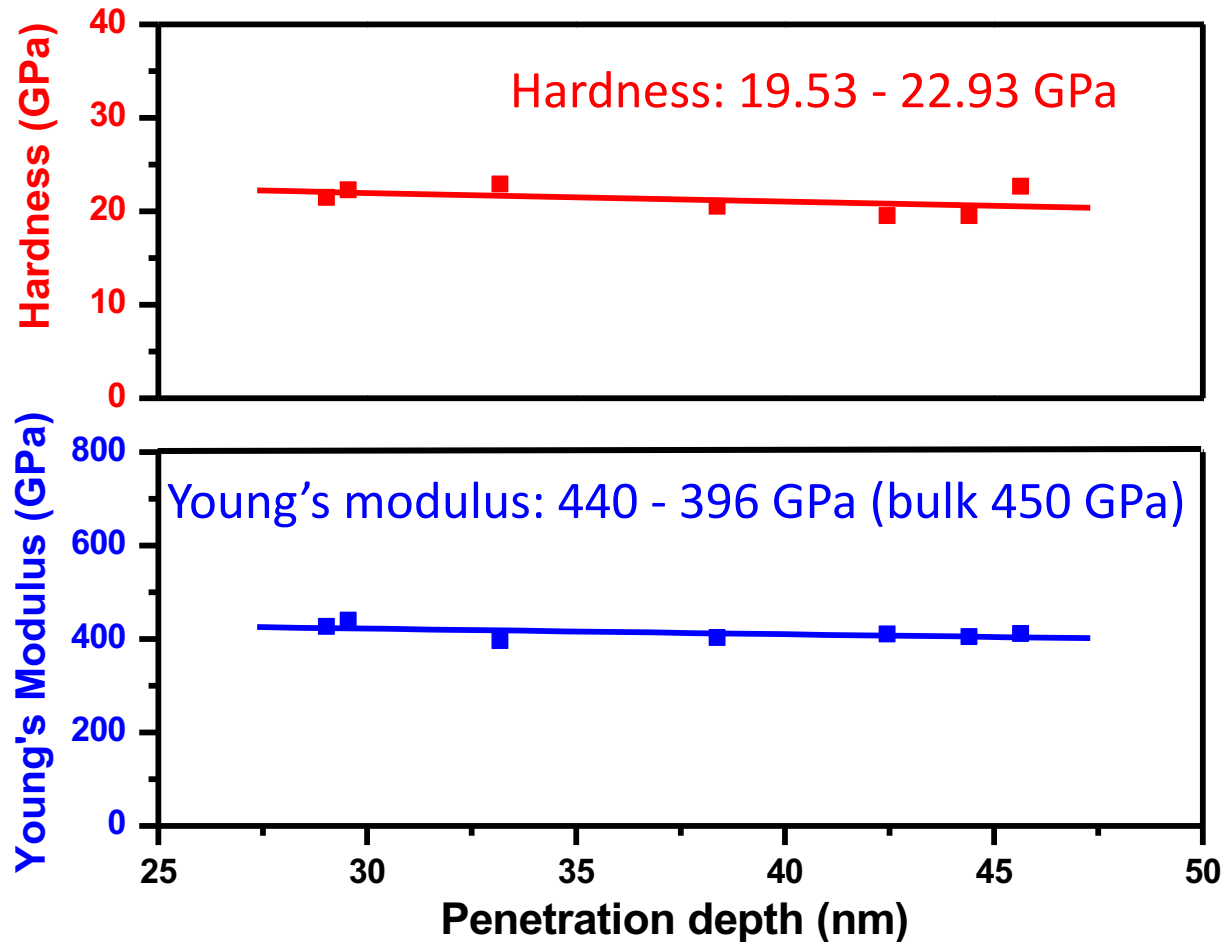
# Heteroepitaxial Simple Metal-Carbide Film by PAD



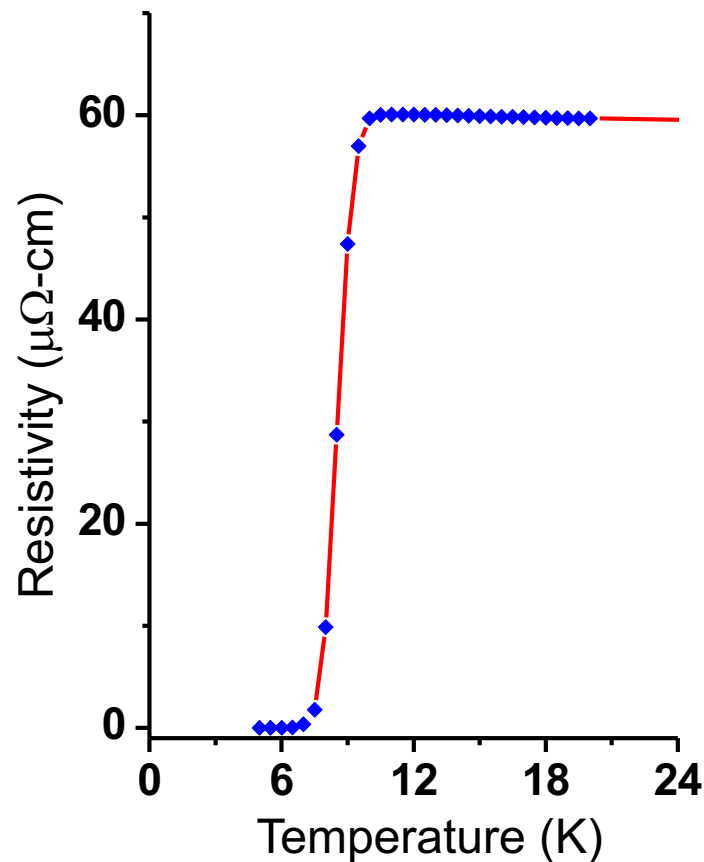
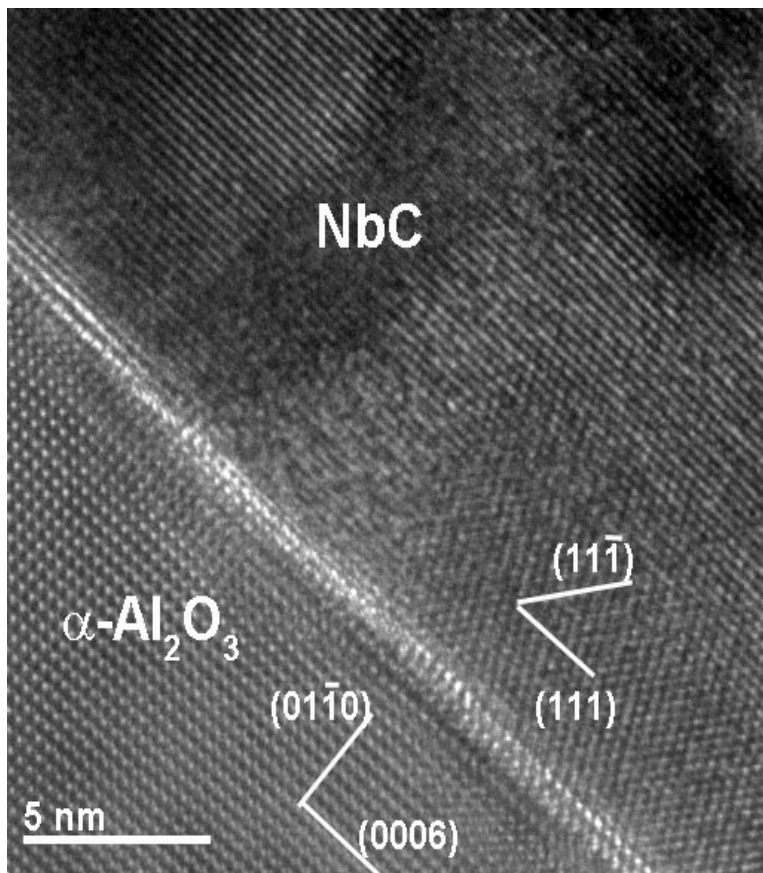
*J. Am. Chem. Soc. 132, 2516 (2010).*

# Desired Mechanical Properties of TiC Films

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# High Quality NbC Film with a Superconducting Transition Temperature of 10 K



*Chem. Commun.* 46, 7837 (2010).

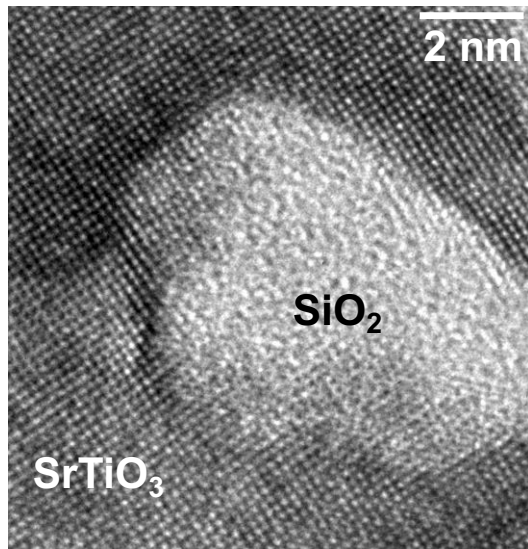
# Outline

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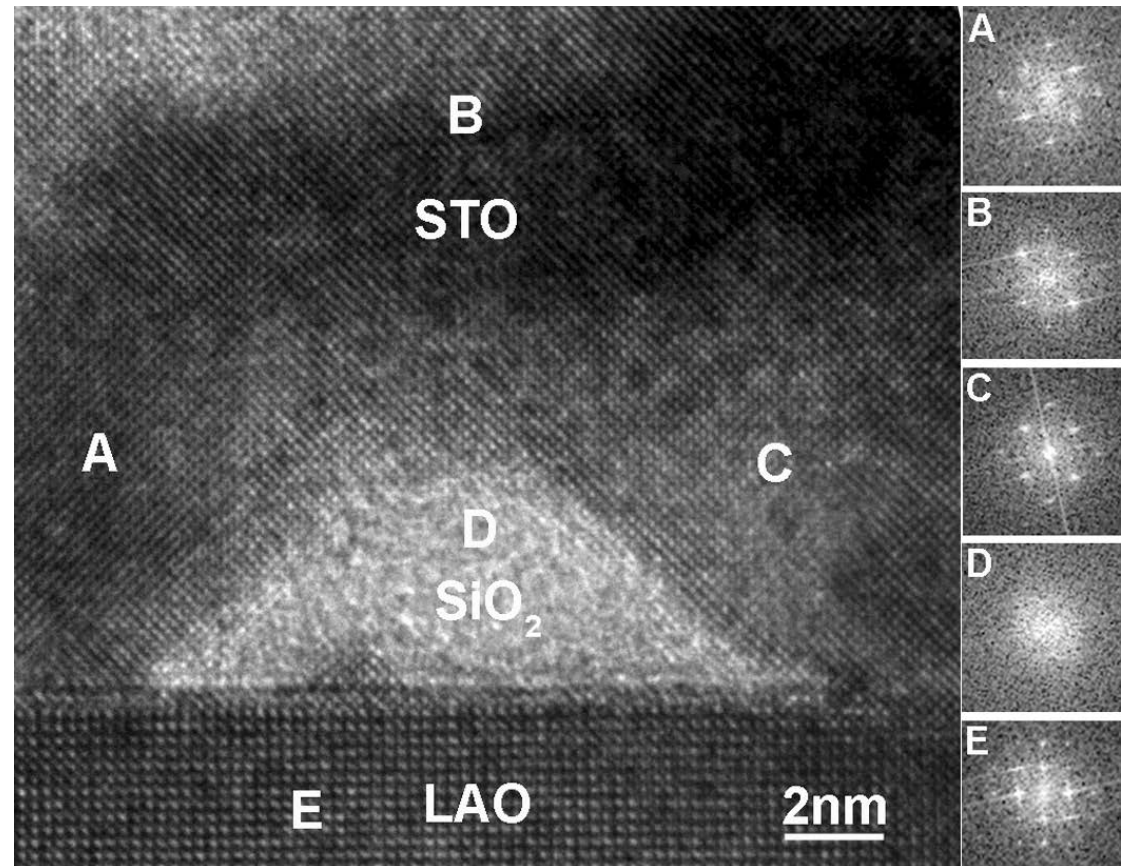


# Epitaxial Nanocomposite Films with Inclusion of Amorphous Nanoparticles



**Vertical:**  
hetero-epitaxial growth

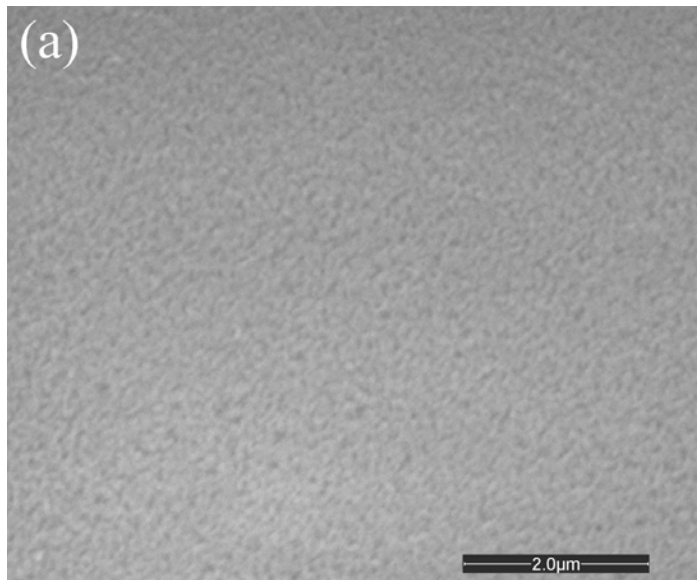
**Lateral:**  
homo- epitaxial growth



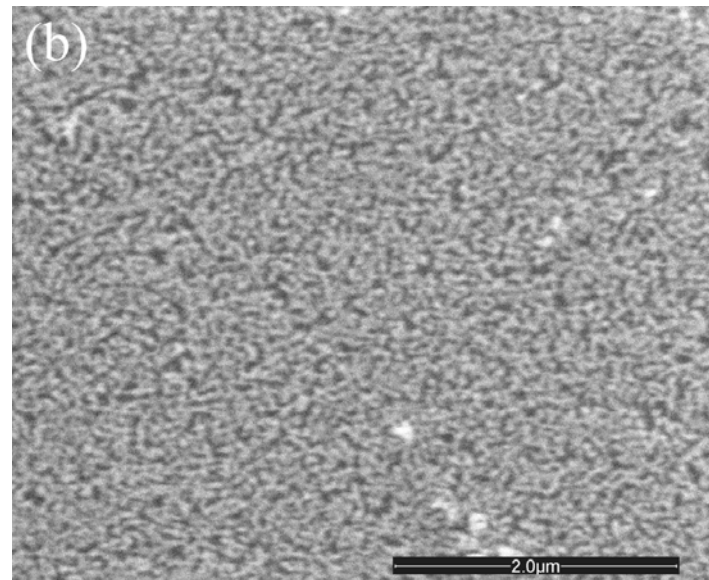
*Angew. Chemie. Int. Ed.* 47, 5768 (2008).

# Porous Epitaxial Films by Etching off $\text{SiO}_2$ Nanoparticles

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**As-deposited composite**

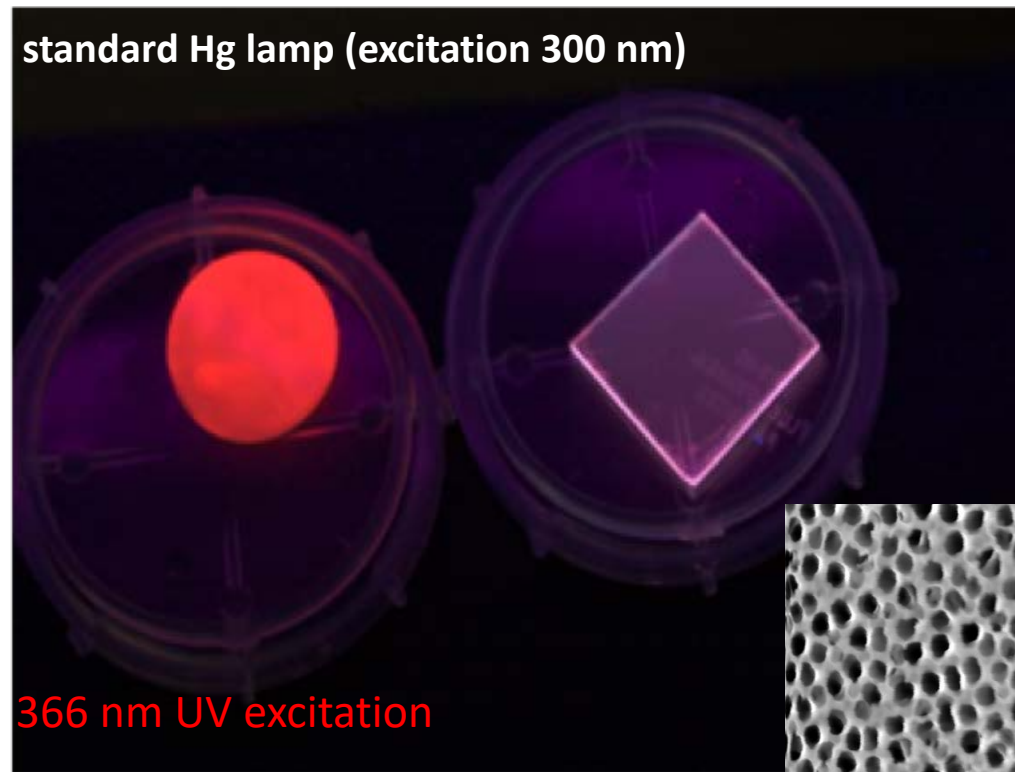


**After etching off  $\text{SiO}_2$**



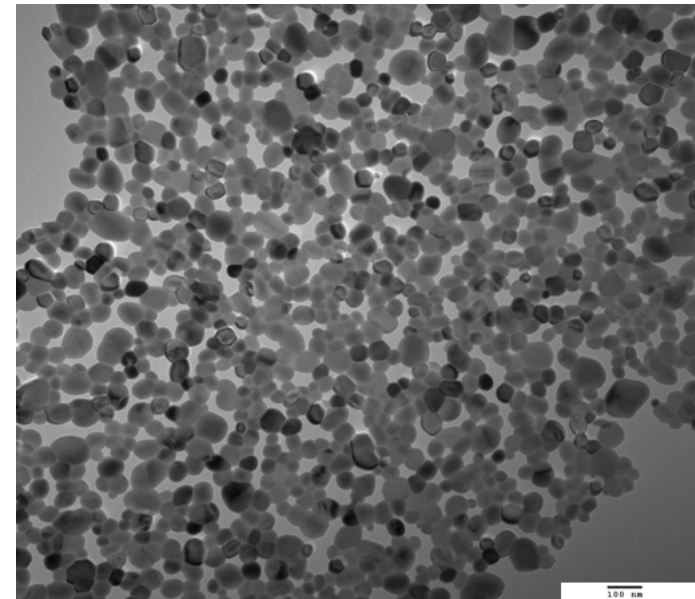
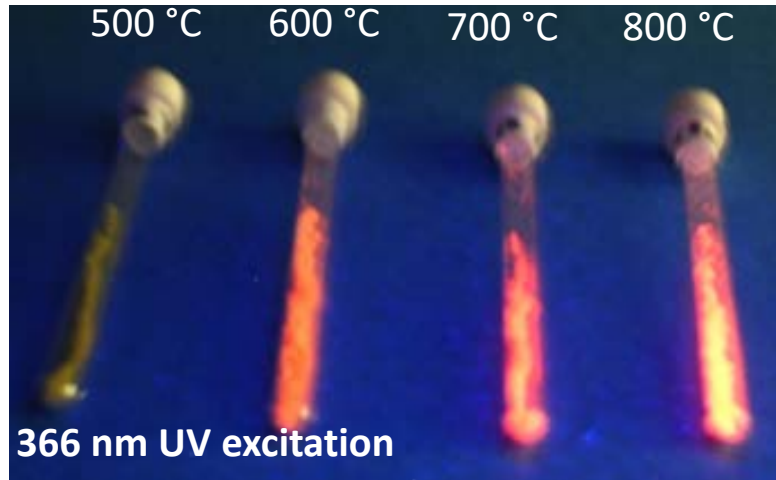
# PAD Application: Coating Phosphors on Nanostructures for Improved Light Output

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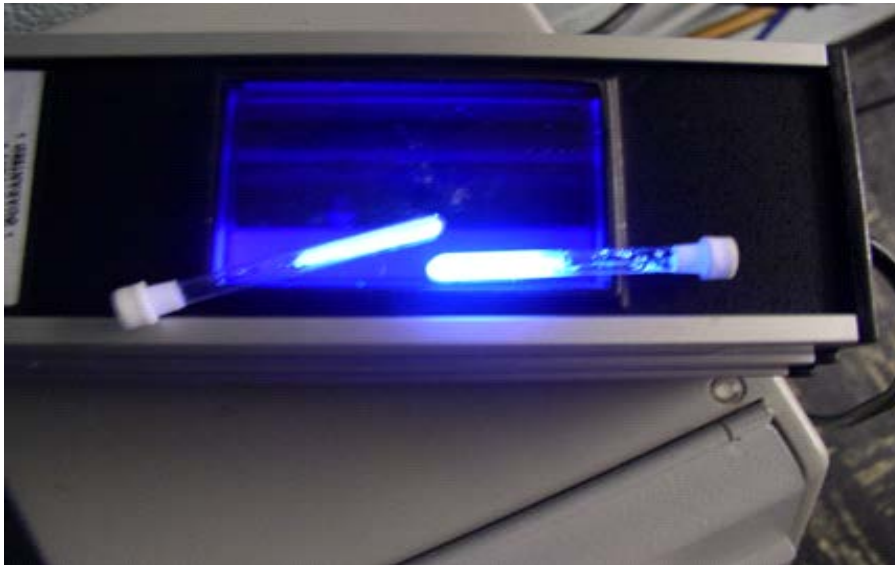
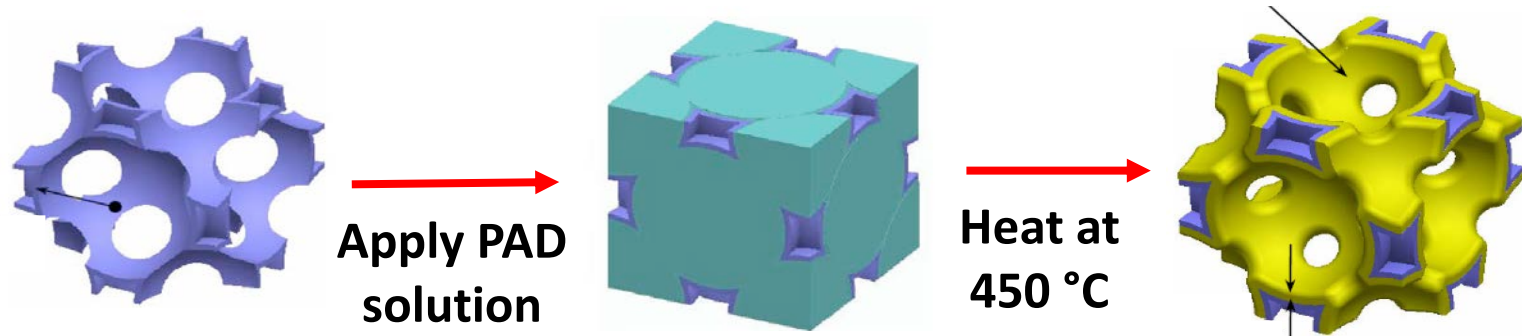
# PAD Application: Synthesis of $\text{Eu:YVO}_4$ Nanoparticle Networks

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**Nanoparticle networks without aggregation**








# PAD Application: Coating Inverse Opals to Achieve a New Class of Scintillating Materials



Hf coated inverse opals photographed in room light excited with a UV lamp.

# Outline

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# Challenges

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- ☞ Thick ( $> 1\mu\text{m}$ ) films
- ☞ Ultra thin ( $< 10\text{ nm}$ ) films
- ☞ Temperature used to de-polymerize the polymers
- ☞ Carbon related issues

# Summary

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- **PAD is a new and powerful coating technique to synthesize electronic materials with desired structural and physical properties.**
- **PAD has no limit to size and shape of objects coated and has broad applications in different fields.**